

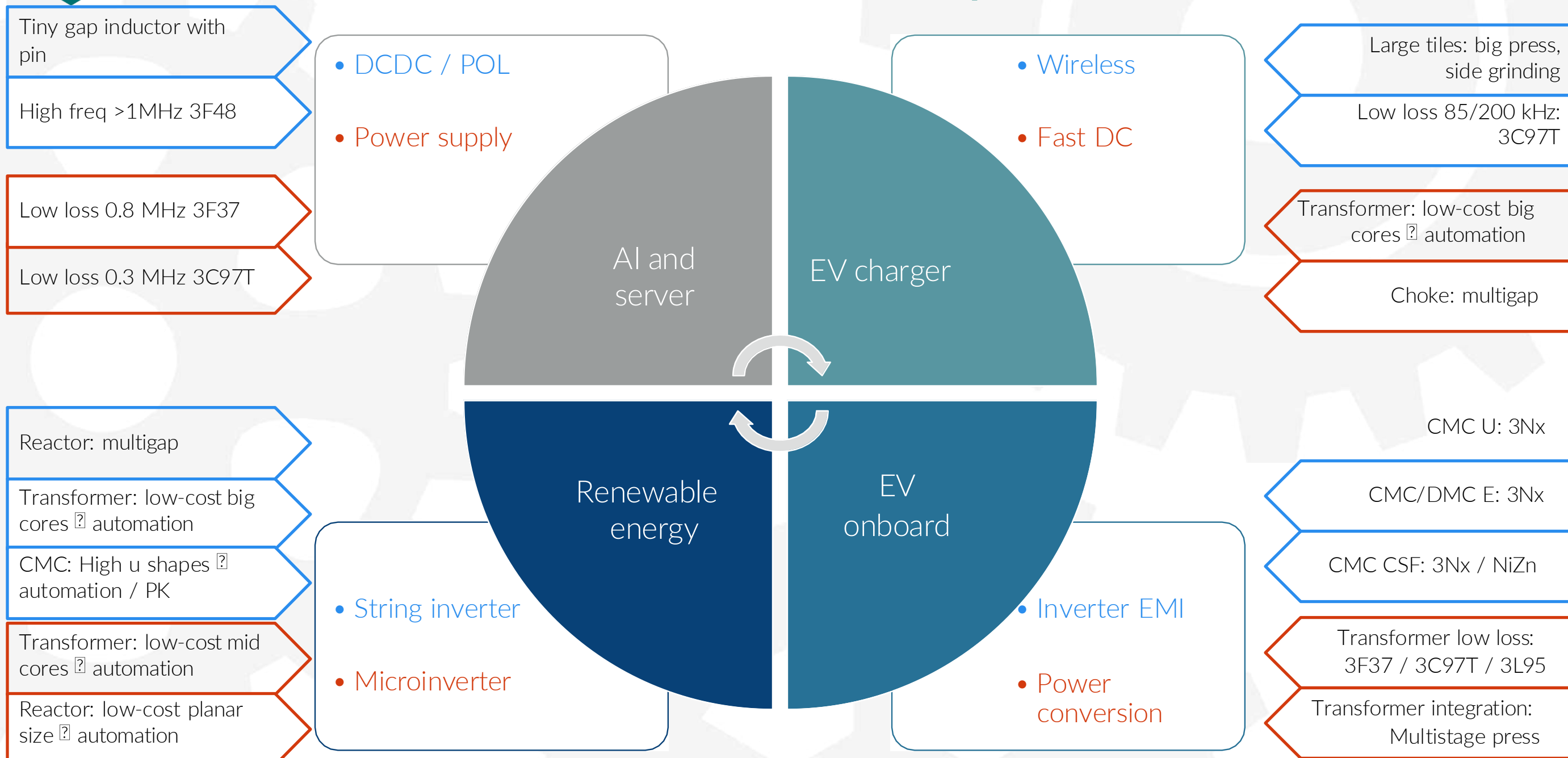
Ferroxcube Roadmap

April 2025





Market links to roadmap

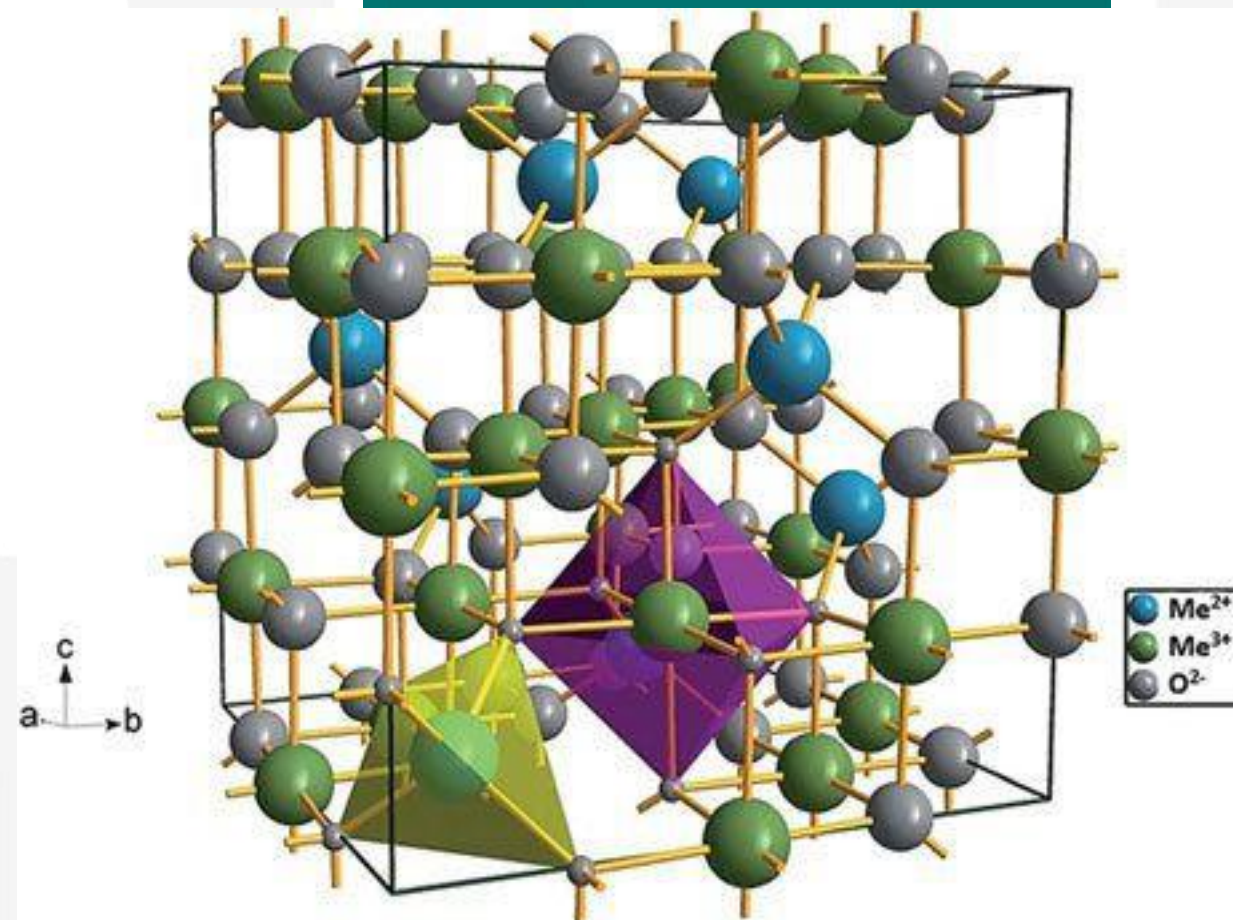


Material Portfolio

New materials

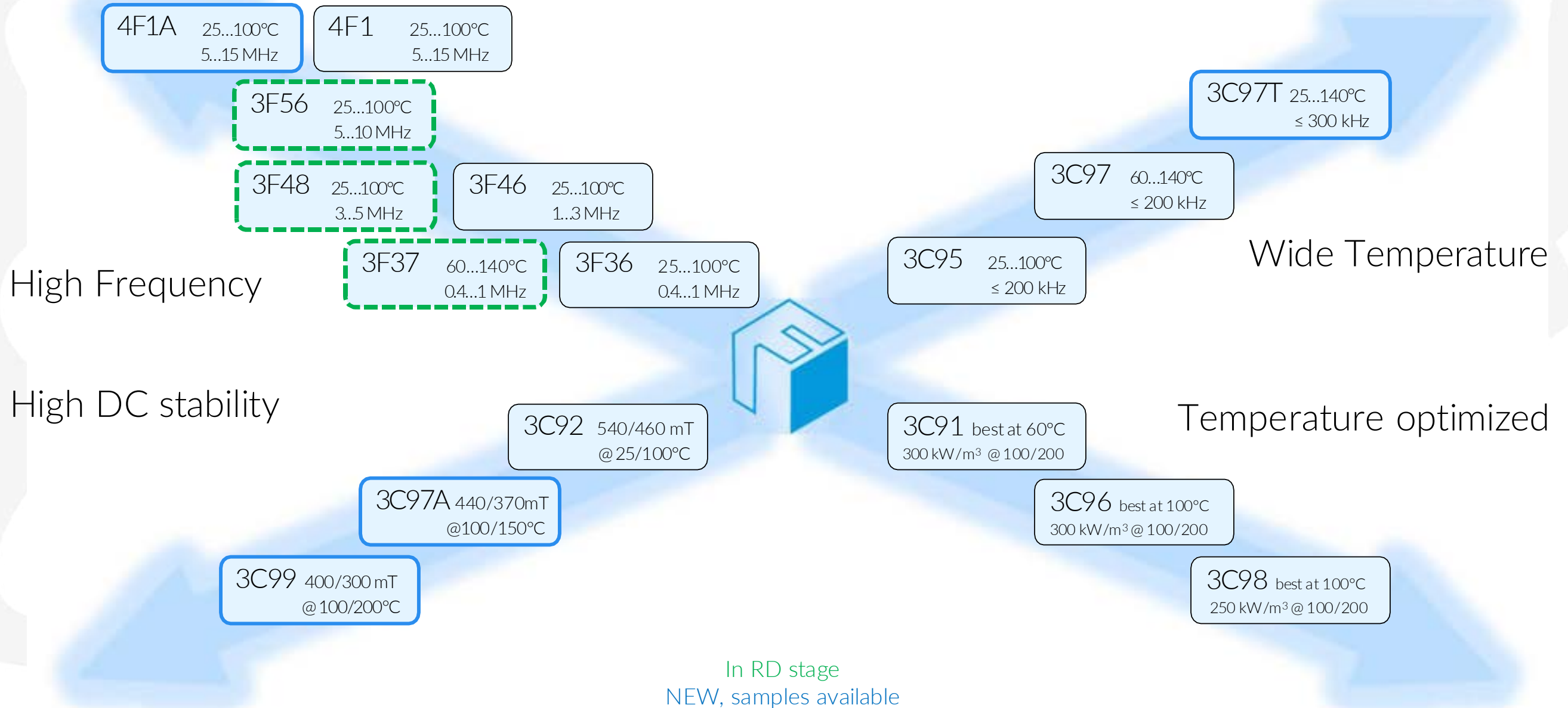
YAGEO GROUP
YAGEO Ferroxcube

THE MAGNETIC
GATEWAY.



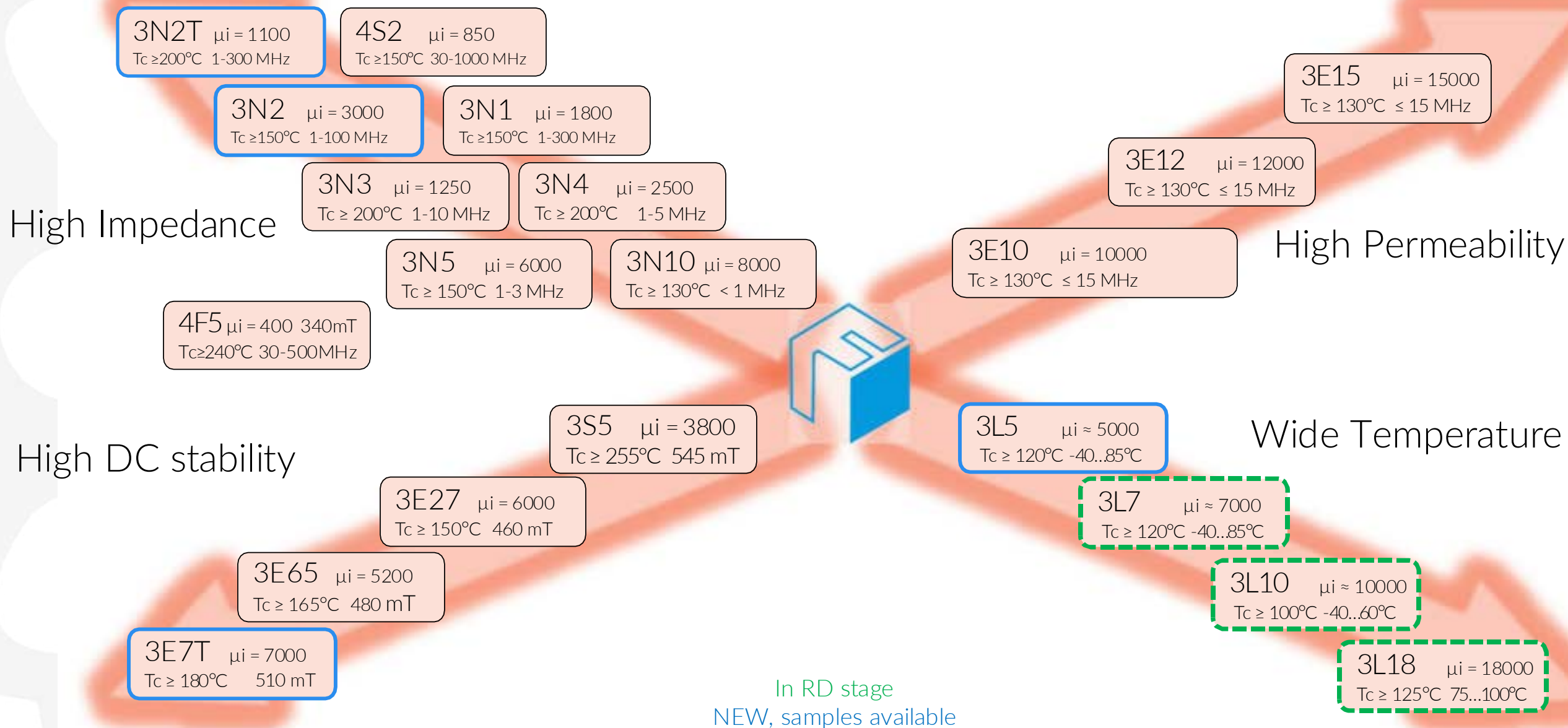


Power conversion materials





EMI suppression materials

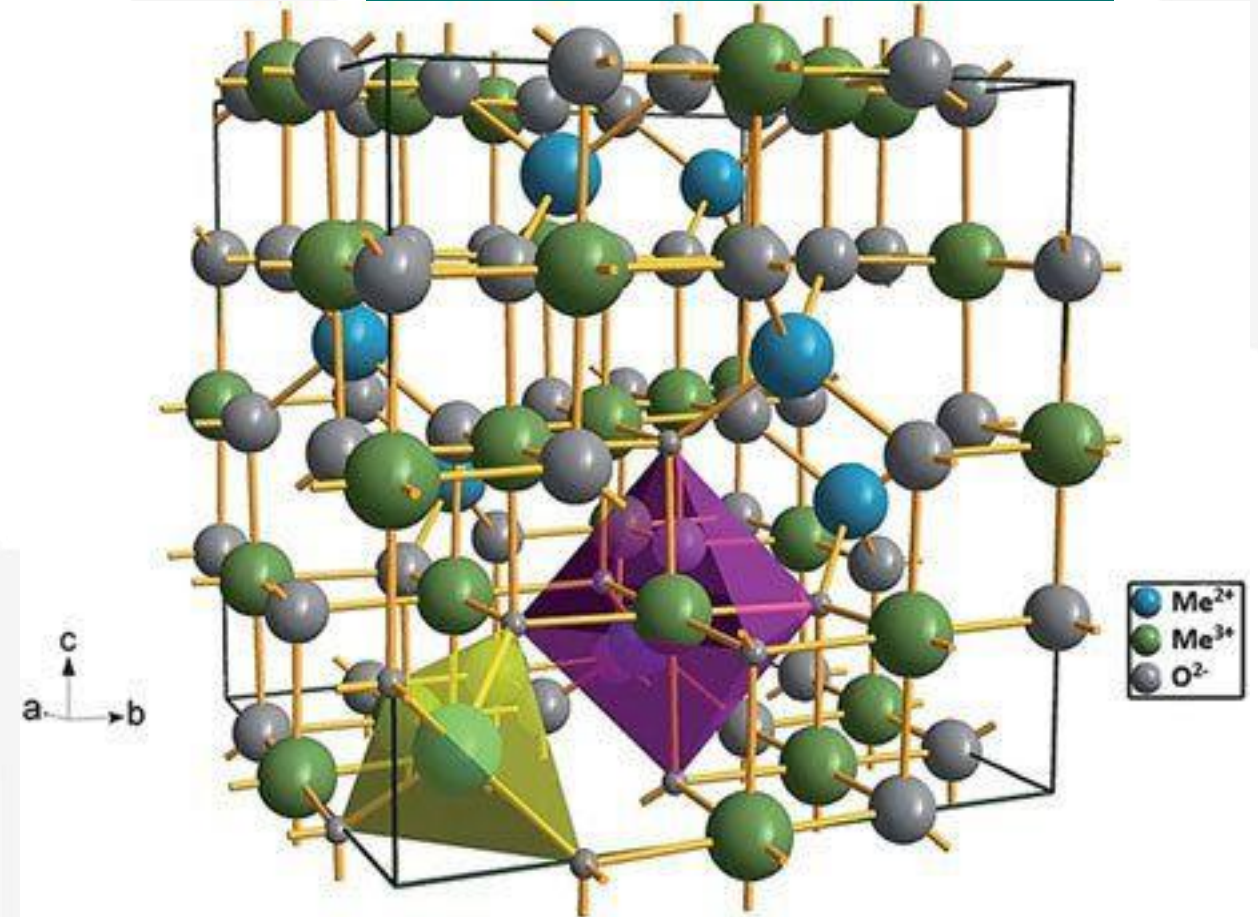


Material Portfolio

Power Materials

YAGEO GROUP
YAGEO Ferroxcube

THE MAGNETIC
GATEWAY.

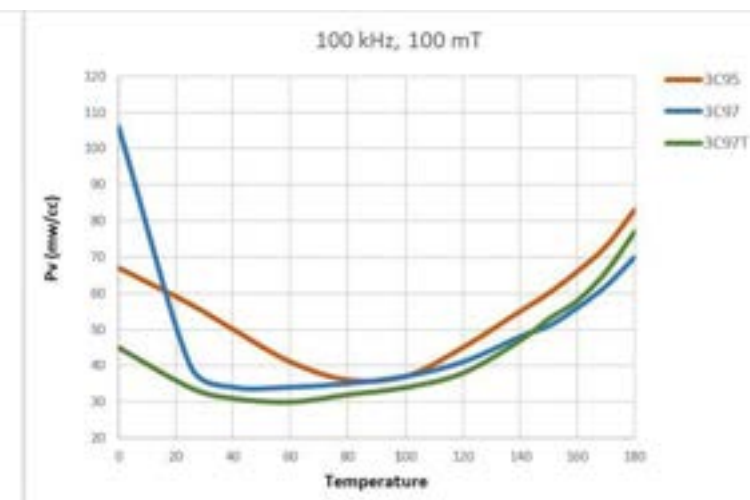
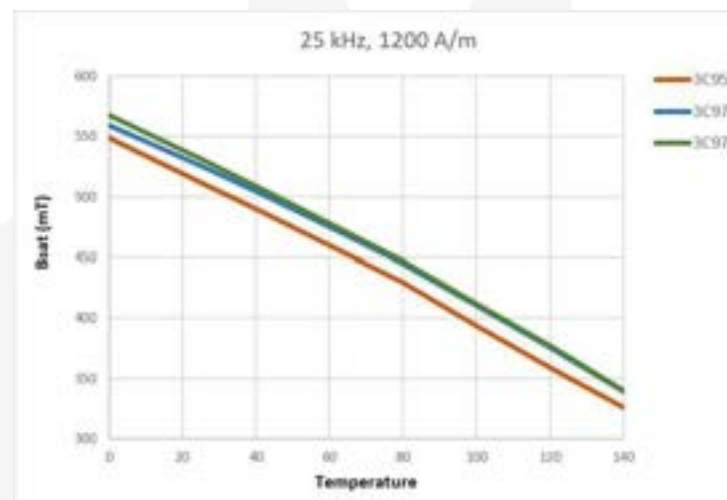
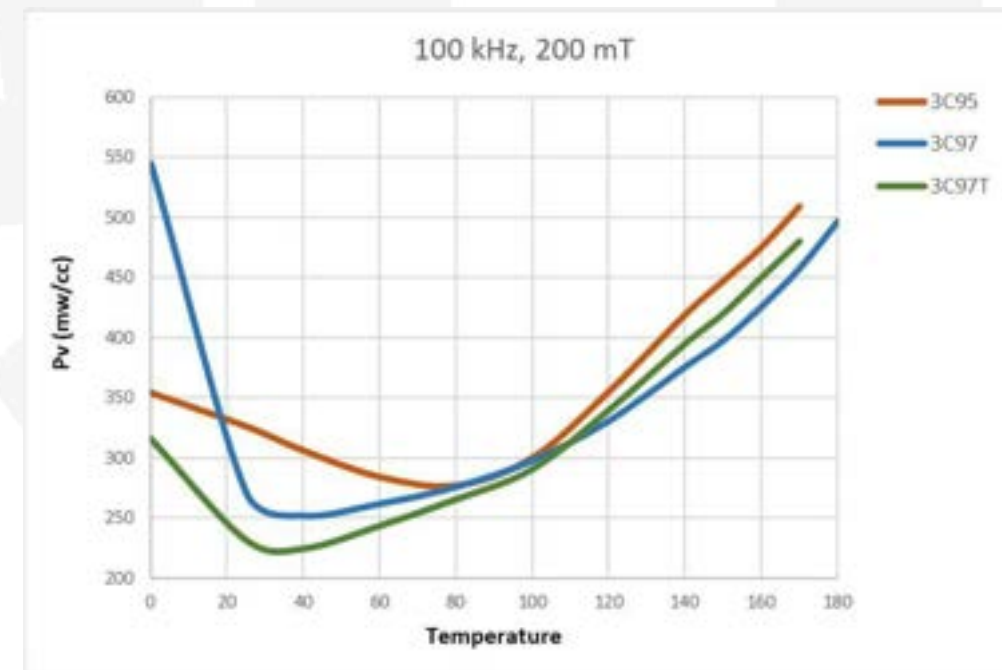




Flat Materials

- 3C95: first flat loss material
 - Best for negative temperatures
- 3C97: optimized for high temperature
- 3C97T**: lowest loss all over the range
 - Good performance at higher freq
 - NEW!**

CONDITIONS		UNIT	3C95	3C97	3C97T
μ i	25°C; 10kHz; 0.25mT		3000	3000	3300
μ a	100°C; 25kHz; 200mT		≈ 5000	≈ 5000	≈ 5000
B	25°C; 10kHz; 1200A/m	mT	≈ 530	≈ 550	≈ 550
	100°C; 10kHz; 1200A/m		≈ 410	≈ 430	≈ 435
	140°C; 10kHz; 1200A/m		≈ 320	≈ 360	≈ 360
Pv	25°C; 100kHz; 200mT	kW/m ³	≈ 350	≈ 290	≈ 230
	100°C; 100kHz; 200mT		≈ 290	≈ 290	≈ 270
	140°C; 100kHz; 200mT		≈ 430	≈ 380	≈ 370
ρ DC	25°C	Ω m	≈ 5	≈ 10	≈ 7
Tc		°C	≥ 215	≥ 215	≥ 250
density		kg/m ³	≈ 4800	≈ 4850	≈ 4900

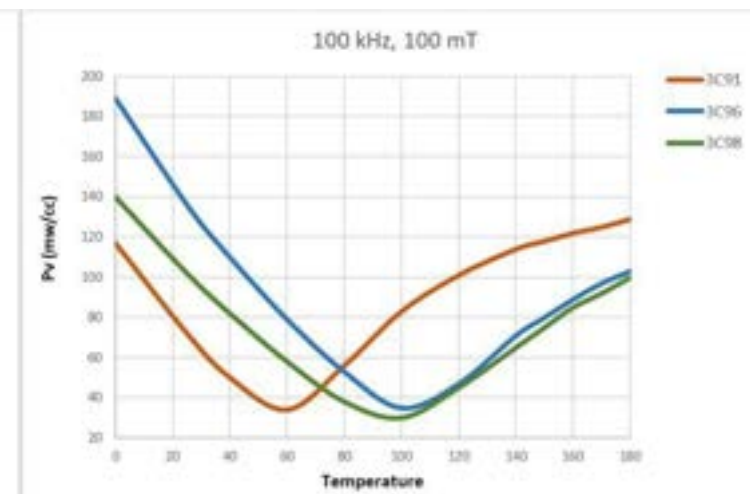
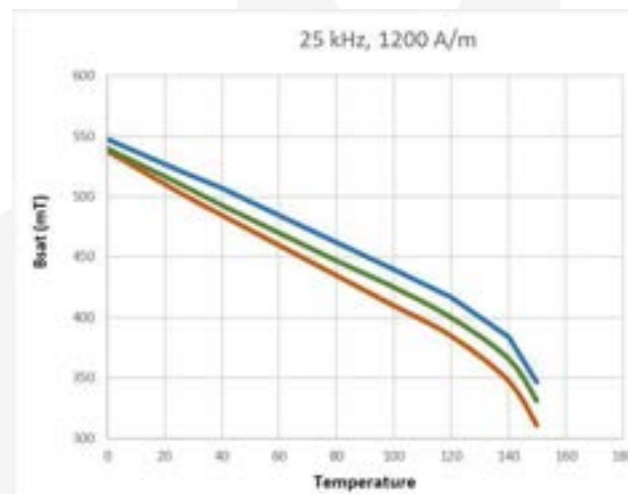
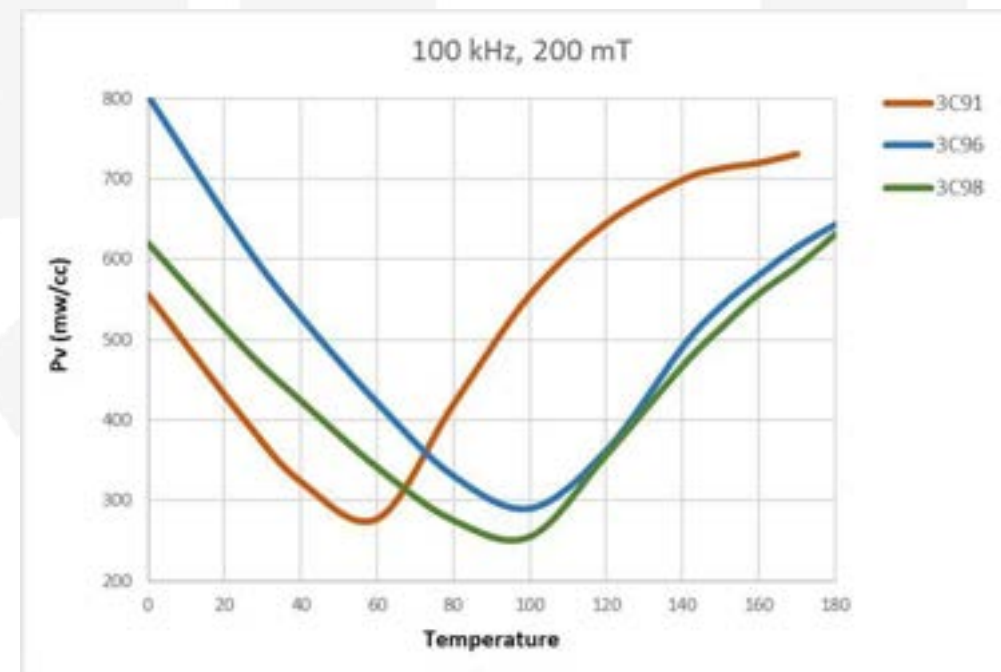




Temperature Optimized

- 3C91: low temperature optimized
 - Handheld devices
- 3C96: 100C optimized
 - Suitable up to 400 kHz
- 3C98: best 100C material
 - Reasonable low loss at low temperature

CONDITIONS		UNIT	3C91	3C96	3C98
μ i	25°C; 10kHz; 0.25mT		3000	2000	2500
μ a	100°C; 25kHz; 200mT		≈ 5500	≈ 5500	≈ 5500
B	25°C; 10kHz; 1200A/m	mT	≈ 470	≈ 500	≈ 530
	100°C; 10kHz; 1200A/m		≈ 370	≈ 440	≈ 440
	140°C; 10kHz; 1200A/m		≈ 330	≈ 370	≈ 380
Pv	60°C; 100kHz; 200mT	kW/m ³	≈ 300	≈ 450	≈ 350
	100°C; 100kHz; 200mT		≈ 550	≈ 300	≈ 250
	140°C; 100kHz; 200mT		≈ 700	≈ 500	≈ 480
ρ DC	25°C	Ω m	≈ 5	≈ 5	≈ 8
Tc		°C	≥ 220	≥ 240	≥ 230
density		kg/m ³	≈ 4800	≈ 4800	≈ 4850

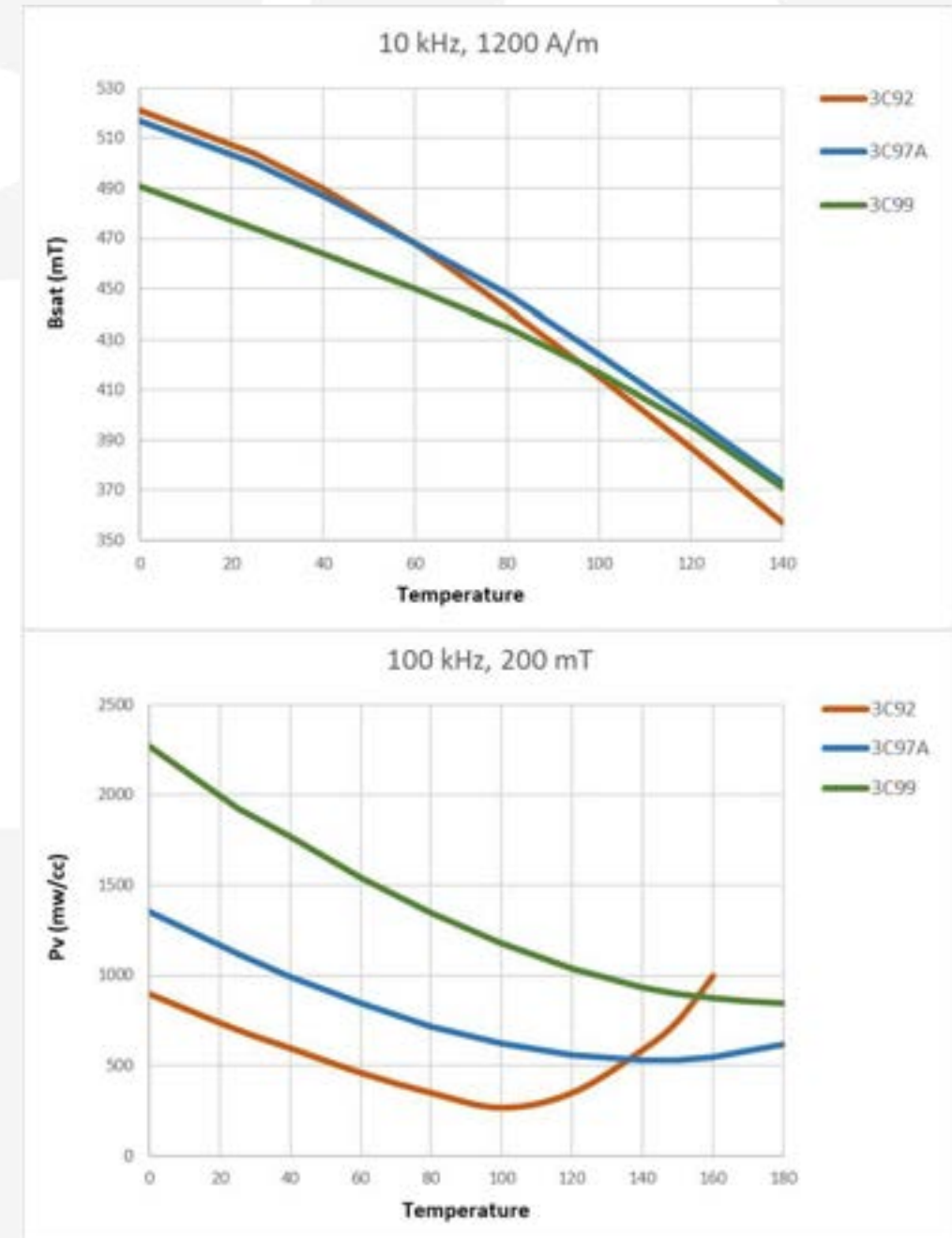




High Bsat

- 3C92: best balance for common applications
 - Low loss, high Bsat up to 140D
- 3C99: Optimized for 200C
- 3C97A: Optimized for operation 120 to 180
 - High Bsat with reasonable losses
 - New!

CONDITIONS		UNIT	3C92	3C99	3C97A
μ_i	25°C; 10kHz; 0.25mT		1800	1100	1100
μ_a	100°C; 25kHz; 200mT		≈ 5500	≈ 4000	≈ 4000
B	100°C; 10kHz; 1200A/m	mT	≈ 460	≈ 450	≈ 440
	150°C; 10kHz; 1200A/m		≈ 350	≈ 370	≈ 370
	200°C; 10kHz; 1200A/m			≈ 320	≈ 320
Pv	60°C; 100kHz; 200mT	kW/m ³	≈ 500	≈ 1500	≈ 350
	100°C; 100kHz; 200mT		≈ 300	≈ 1200	≈ 250
	150°C; 100kHz; 200mT		≈ 600	≈ 900	≈ 500
ρ_{DC}	25°C	Ωm	≈ 5	≈ 6	≈ 8
Tc		°C	≥ 270	≥ 300	≥ 280
density		kg/m ³	≈ 4800	≈ 4800	≈ 4800

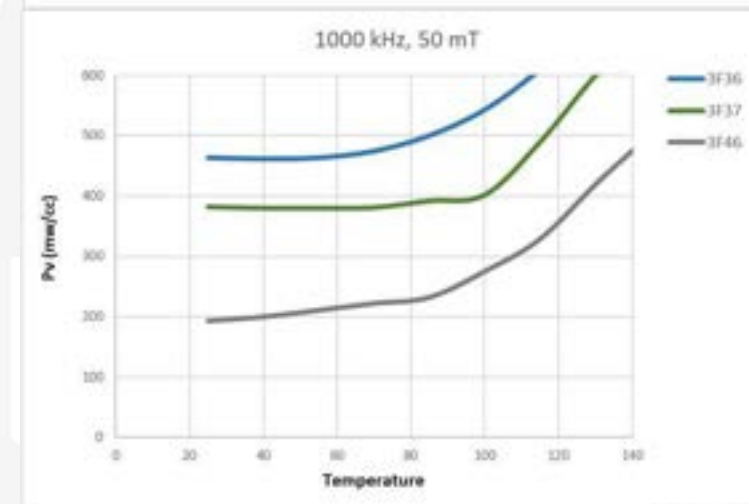
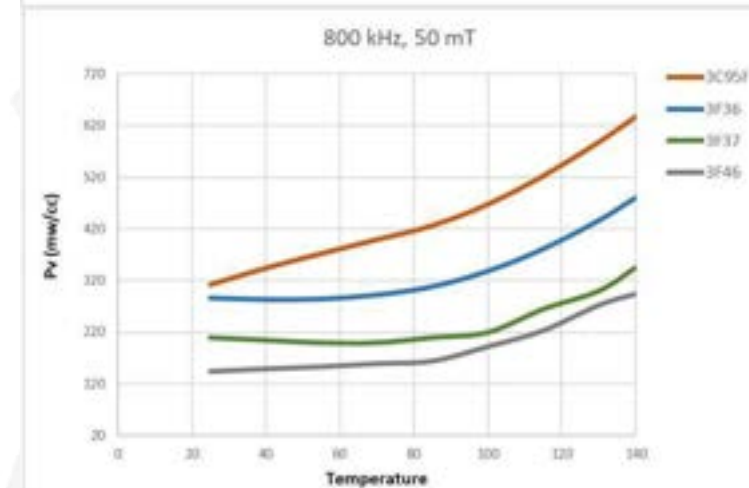
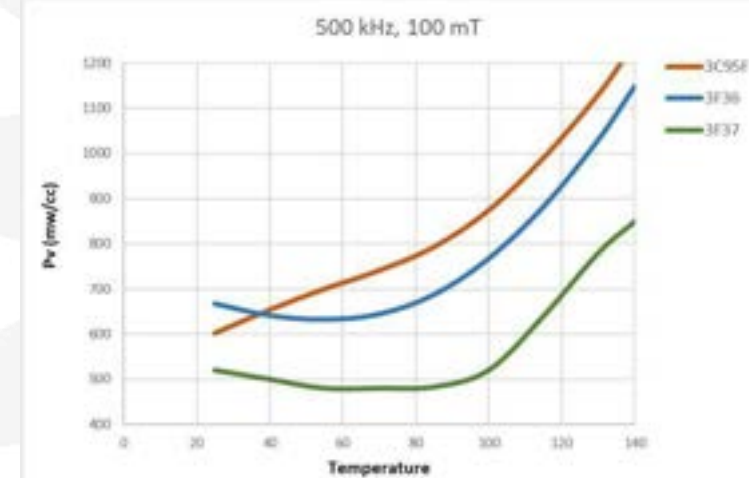




High Frequency: 400 to 1000 kHz

- 3Cxx materials are best up to 300 kHz
- 3F36: good for 400 to 700 kHz
 - Good for large size
- 3F37: best for 400 to 800 kHz
 - New! Launch on Q2
- 3F46: best 800 to 2000 kHz
 - Recommended for small sizes

CONDITIONS		UNIT	3F36	3F37	3F46
μ i	25°C; 10kHz; 0.25mT		1600	1500	650
μ a	100°C; 25kHz; 200mT		≈ 2400	≈ 2500	≈ 1500
B	25°C; 10kHz; 1200A/m	≈ 520 mT	≈ 450	≈ 550	
	100°C; 10kHz; 1200A/m		≈ 420	≈ 370	≈ 450
Pv	100°C; 500kHz; 100mT		≈ 700	≈ 520	
	100°C; 800kHz; 50mT	kW/m ³	≈ 350	≈ 220	≈ 200
	100°C; 1 MHz; 50mT		≈ 550	≈ 400	≈ 150
ρ DC	25°C	Ω m	≈ 12	≈ 15	≈ 5
Tc		°C	≥ 230	≥ 230	≥ 280
density		kg/m ³	≈ 4750	≈ 4750	≈ 4750



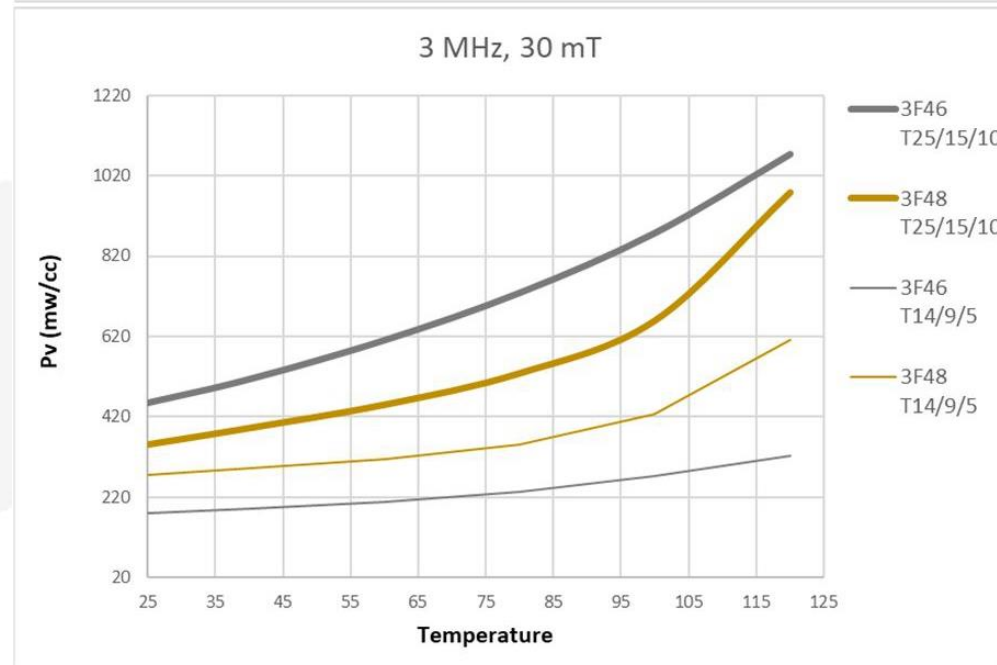
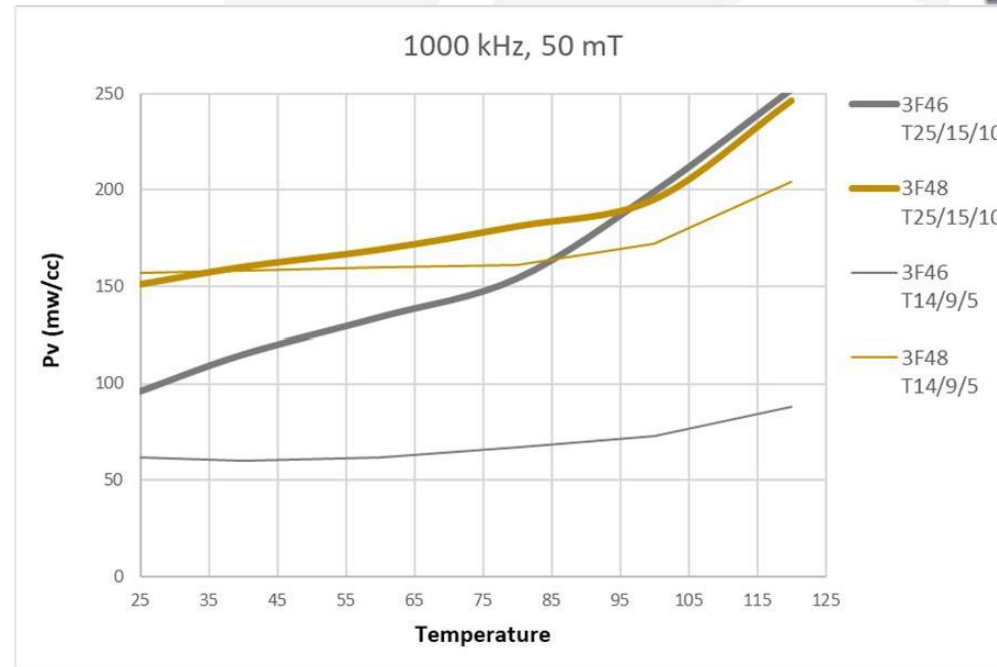


High Frequency: 1 to 3 MHz

- 3F48: best for large sizes
 - Specially in high frequency beyond 2 MHz
 - New! Still in development
- 3F46: best 800 to 2000 kHz
 - Recommended for small sizes

	CONDITIONS	UNIT	3F48	3F46
μ_i	25°C; 10kHz; 0.25mT		600	650
μ_a	100°C; 25kHz; 200mT		≈ 1500	≈ 1500
B	25°C; 10kHz; 1200A/m	mT	≈ 550	≈ 550
	100°C; 10kHz; 1200A/m		≈ 450	≈ 450
Pv	100°C; 1 Mhz; 50mT	kW/m3	≈ 180	≈ 150
	100°C; 3 MHz; 30mT		≈ 250	≈ 500
ρ_{DC}	25°C	Ωm	≈ 20	≈ 5
Tc		°C	≥ 280	≥ 280
density		kg/m ³	≈ 4750	≈ 4750

Data measured on T14/9/5



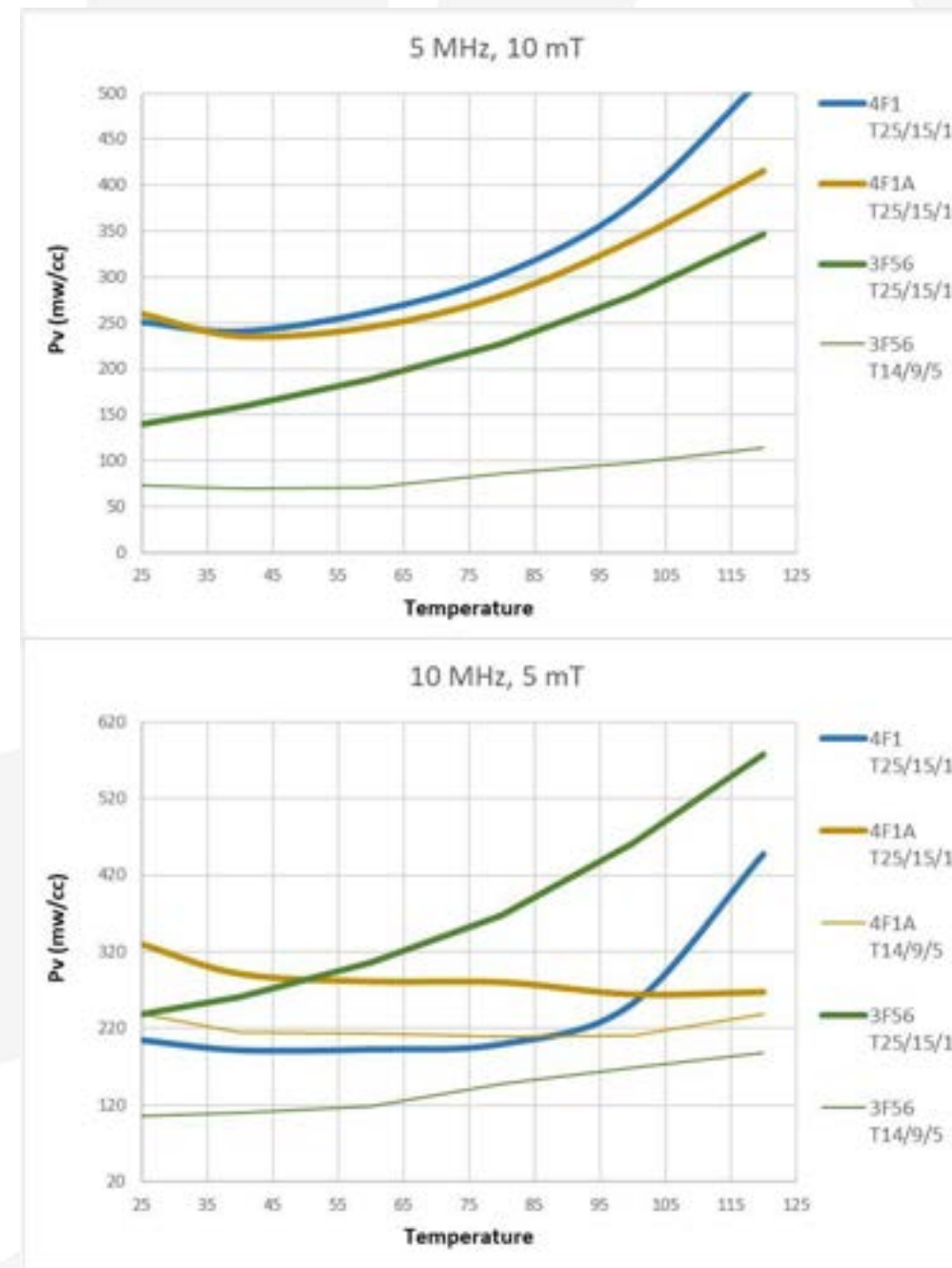


High Frequency: 5 to 15 MHz

- 3F56: MnZn material optimized for 5 MHz
 - Good up to 10 MHz on small sizes
 - New! Still in development
- 4F1: Best for 7 to 15 MHz, including ISM 13.56 MHz
 - NiZn: no significant impact of size
- 4F1A: flat version of 4F1 with improved losses at high temperature
 - New! Samples available on request

CONDITIONS		UNIT	3F56	4F1A	4F1
μ_i	25°C; 10kHz; 0.25mT		500	80	80
μ_a	100°C; 25kHz; 200mT		≈ 2000	≈ 300	≈ 300
B	25°C; 10kHz; 1200A/m	mT	≈ 520	≈ 320	≈ 320
	100°C; 10kHz; 1200A/m		≈ 420	≈ 260	≈ 260
Pv	100°C; 3 MHz; 30mT	kW/m ³	≈ 700		
	100°C; 5 MHz; 10mT		≈ 100	≈ 350	≈ 400
	100°C; 10 MHz; 5mT		≈ 170	≈ 200	≈ 250
ρ_{DC}	25°C	Ωm	≈ 100	≈ 10 ⁶	≈ 10 ⁶
Tc		°C	≥ 230	≥ 260	≥ 260
density		kg/m ³	≈ 4750	≈ 4600	≈ 4600

Data measured on T14/9/5

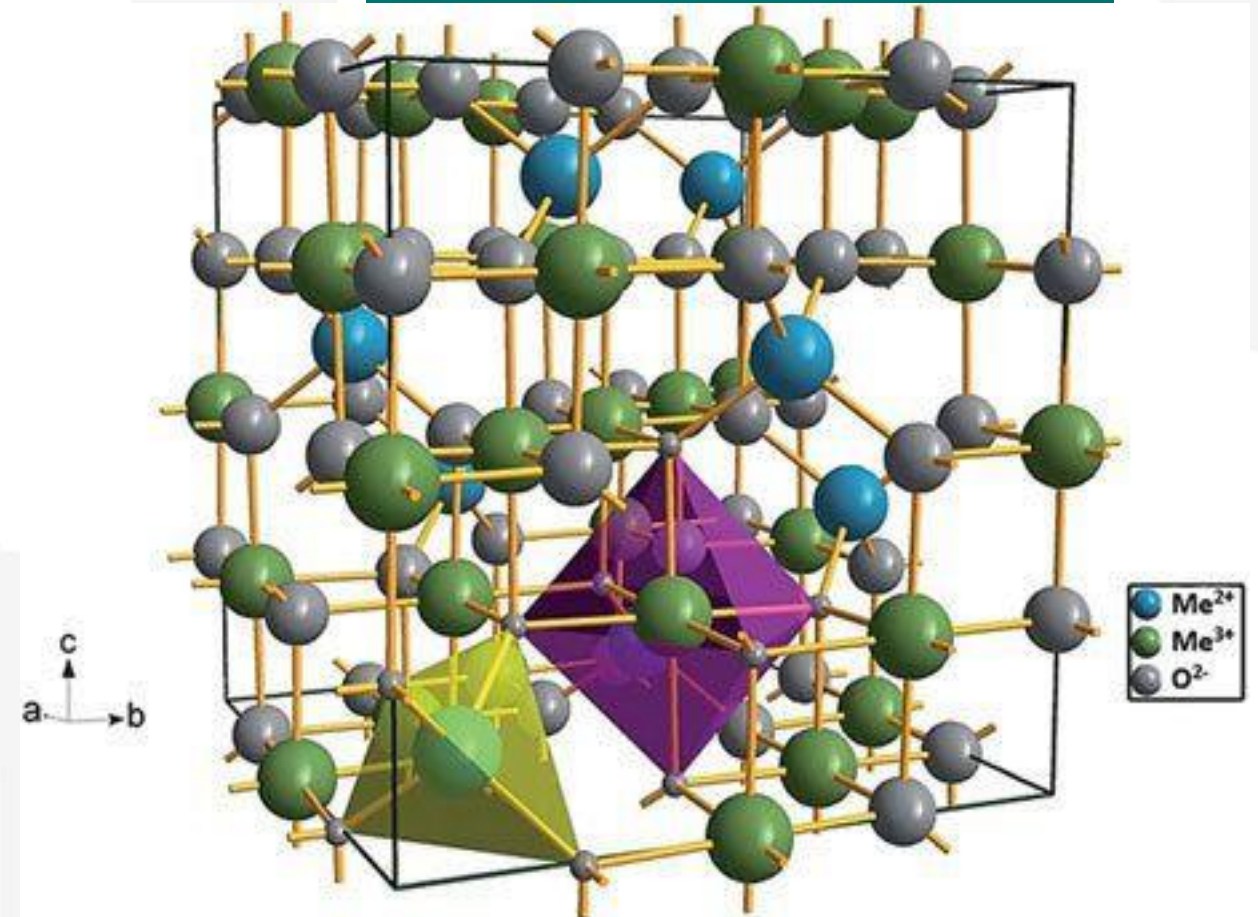


Material Portfolio

EMI Materials

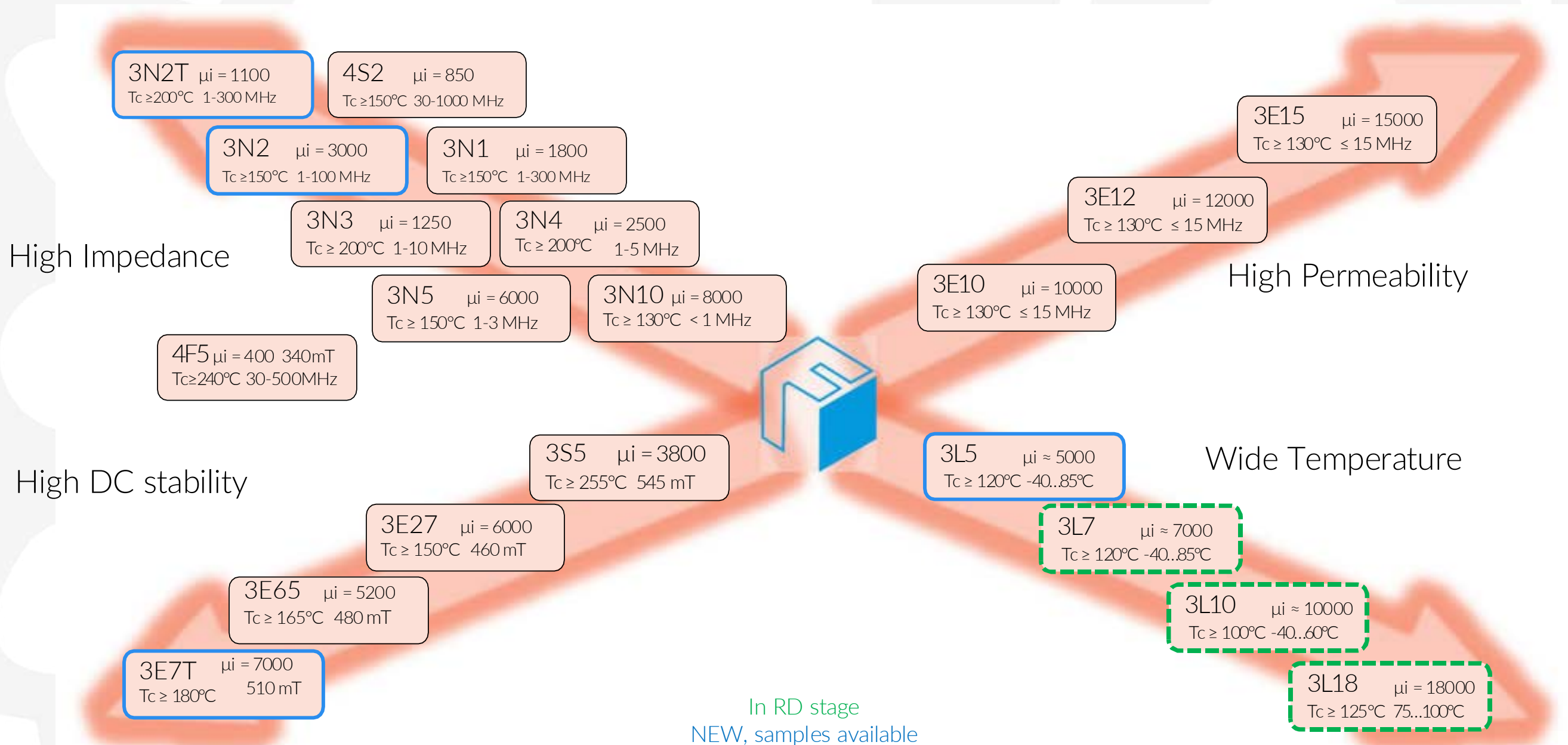
YAGEO GROUP
YAGEO Ferroxcube

THE MAGNETIC
GATEWAY.





EMI Suppression Materials





3E7T – High Perm with highest Tc

Highest permeability (7k) with Tc >180°C

Wide band EMI suppression up to 10 MHz

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	7000 $\pm$ 20%	
B	25°C; 10kHz; 1200A/m	$\approx$ 510	mT
	100°C; 10kHz; 1200A/m	$\approx$ 360	
$\tan\delta/\mu_i$	25°C; 30kHz; 0.25mT	$\leq 3 \cdot 10^{-6}$	
	25°C; 100kHz; 0.25mT	$\leq 9 \cdot 10^{-6}$	
ρ_{DC}	25°C	$\approx$ 0.1	Ωm
Tc		$\geq$ 180	°C
density		$\approx$ 4900	kg/m ³

Typical performance of unstressed ring T25/15/10

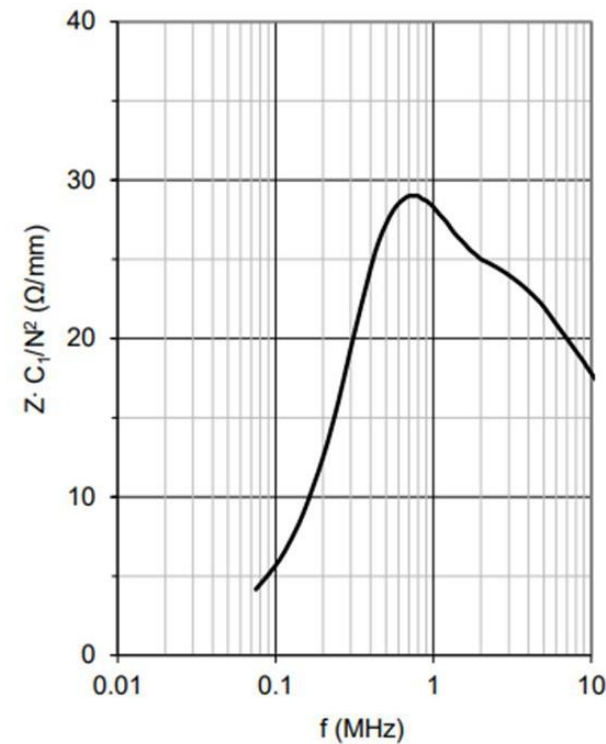


Fig.5 Normalized impedance as a function of frequency

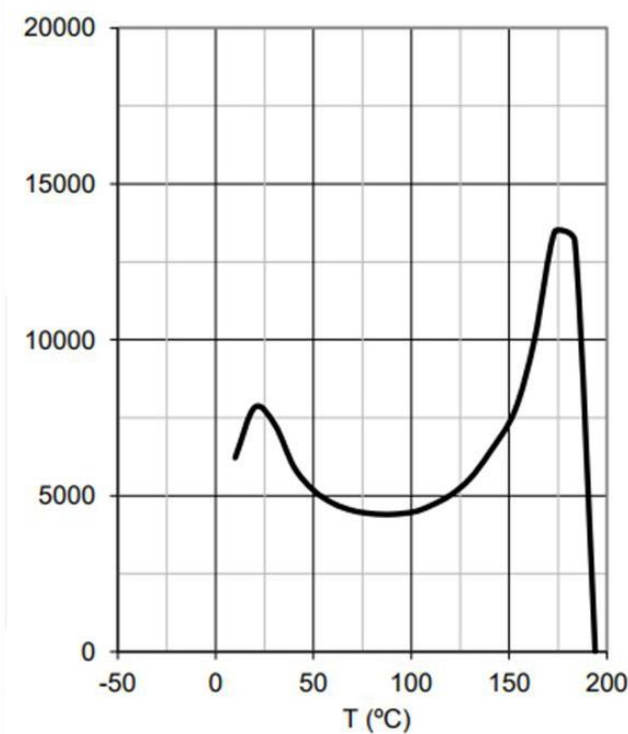


Fig.2 Initial permeability as a function of temperature

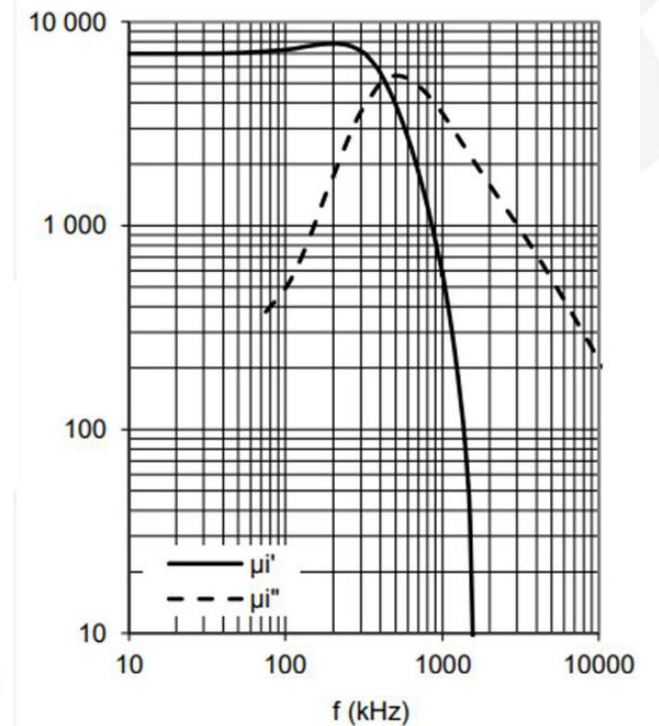
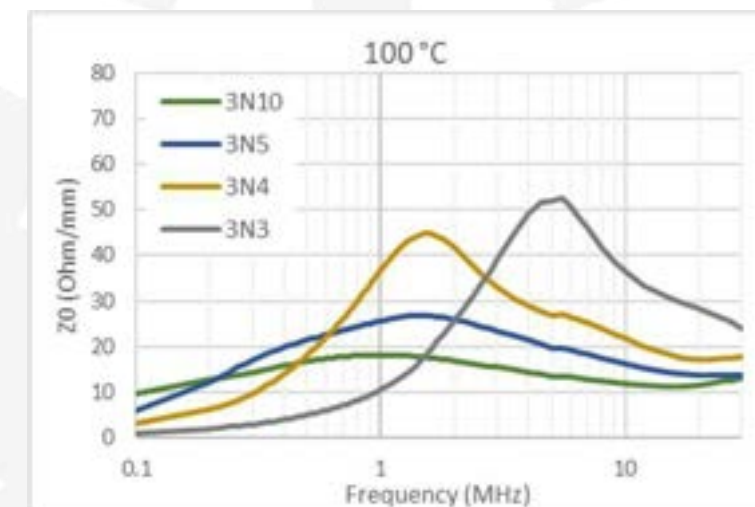
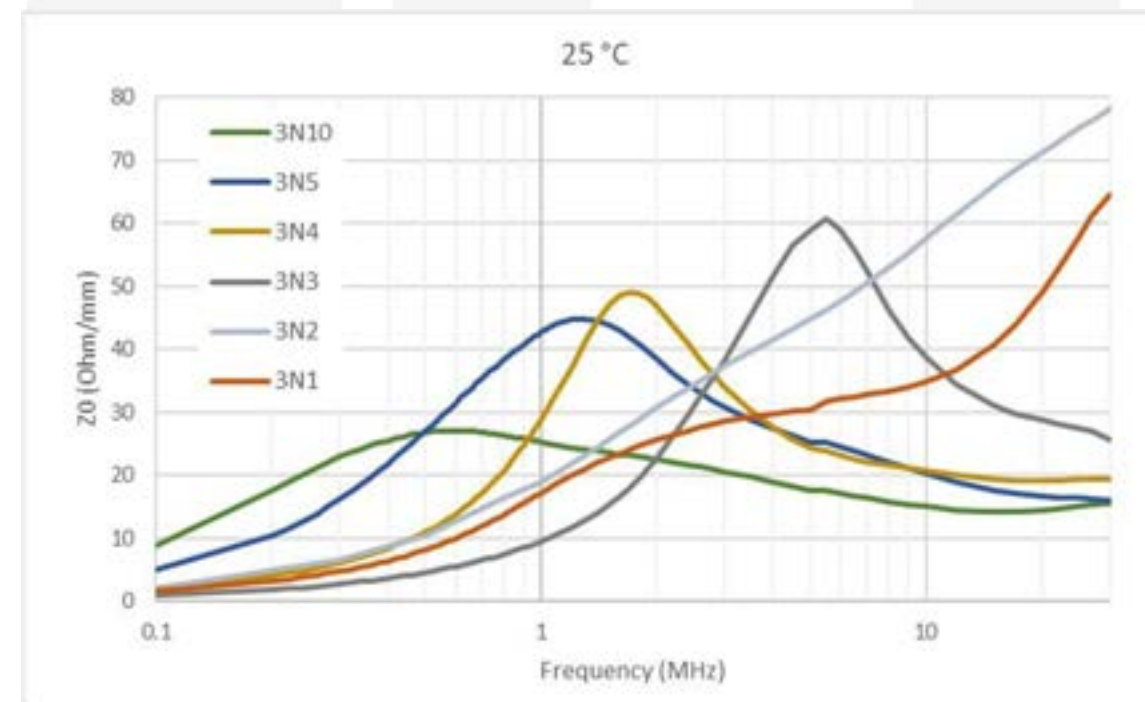


Fig.1 Complex permeability as a function of frequency



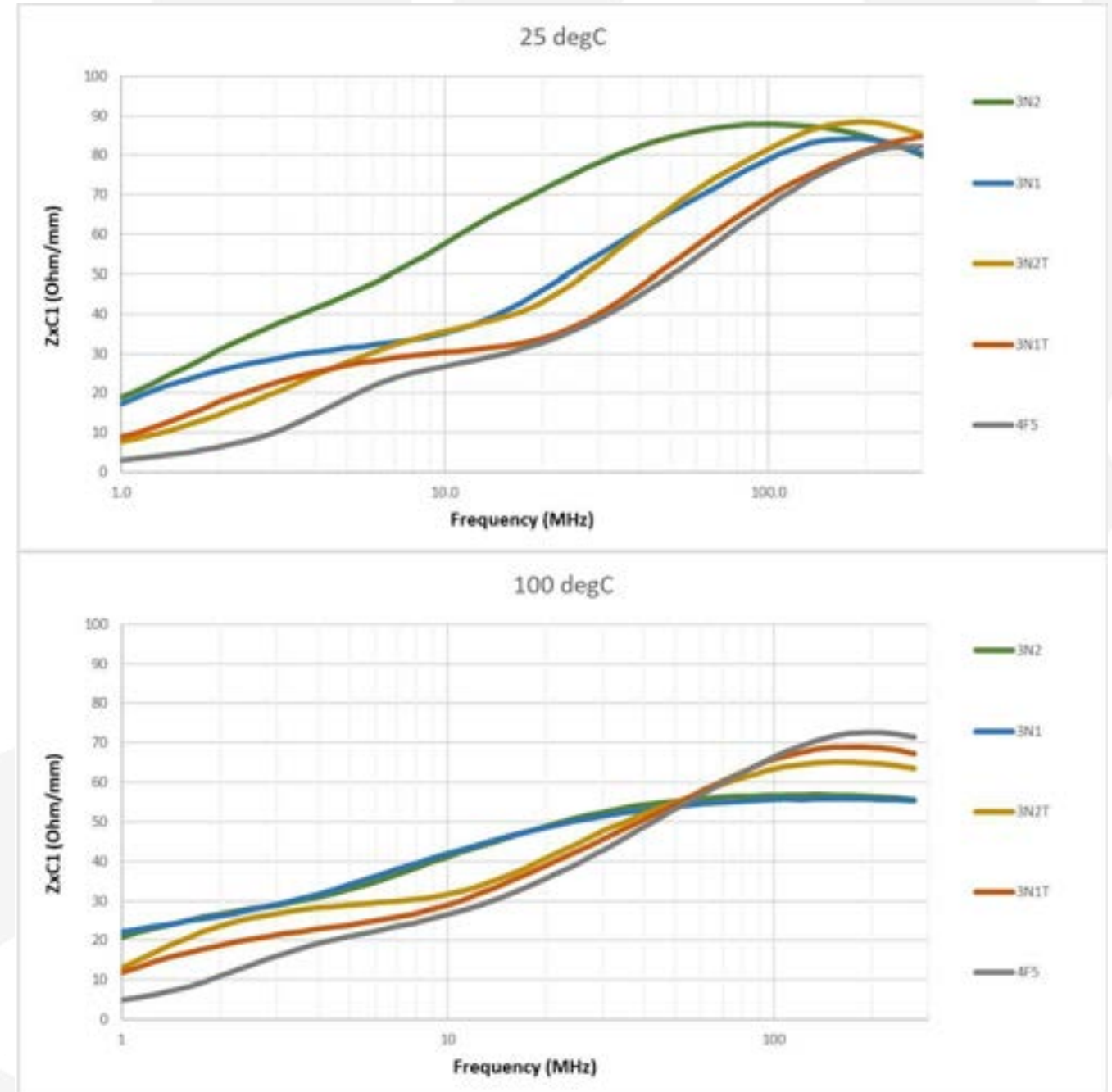
3N series for low frequency up to 30 MHz

- High resistivity MnZn materials
- 3N1: Reasonable impedance 10 to 30 MHz
- 3N2: Highest impedance 10 to 30
 - Not affected by eddy currents (high resistivity)
 - New! Preferred for broadband filtering
- 3N3: High T_c (200), high B_{sat} , low perm
- 3N4: High T_c (200), High B_{sat} , $\mu=3000$
- 3N5: Broad band LF, $T_c > 150$
- 3N10: Highest low freq impedance < 1 MHz
 - Performance dependent on cross section (eddy currents)



High frequency suppression: up to 300 MHz

- High resistivity MnZn materials
- 3N1: Optimized for 100 MHz
- 3N2: Highest impedance 10 to 100
 - High μ , also effective at low freq
 - New! Preferred for broadband filtering
- 3N1T: High Tc (200)
- 3N2T: High Tc with improved Z
 - New! Preferred for high temperature
- 4F5: NiZn high Tc high Bsat





Material selection: common or differential mode

Common

Very high Z
10 ~ 100 MHz

High rho

$T_c > 150$

Alternative to
NiZn

Common &
Differential

High Z
10 ~ 100 MHz

High rho

$T_c > 200$

High Bsat

Alternative to
NiZn

Common

Very high Z
0.3 ~ 100 MHz

High rho

$T_c > 150$

$\mu_i = 3000$

Alternative to
NiZn

CM, DM and
Insert in NanoC

Z 0.3 ~ 10 MHz

High Bsat

$T_c > 200$

$\mu_i = 2500$ 3N4

$\mu_i = 1250$ 3N3

Common

Z 0.3 ~ 10 MHz

$T_c > 150$

$\mu_i = 6000$

Common

Z 0.3 ~ 5 MHz

$T_c > 150$

$\mu_i = 6000$

3N1 $\mu_i = 1800$
 $T_c \geq 150^\circ\text{C}$ 30-100 MHz

3N2T $\mu_i = 1100$
 $T_c \geq 200^\circ\text{C}$ 30-100 MHz

3N2 $\mu_i = 3000$
 $T_c \geq 200^\circ\text{C}$ 30-100 MHz

3N3 $\mu_i = 1250$
 $T_c \geq 200^\circ\text{C}$ 3-20 MHz

3N4 $\mu_i = 2500$
 $T_c \geq 200^\circ\text{C}$ 1-5 MHz

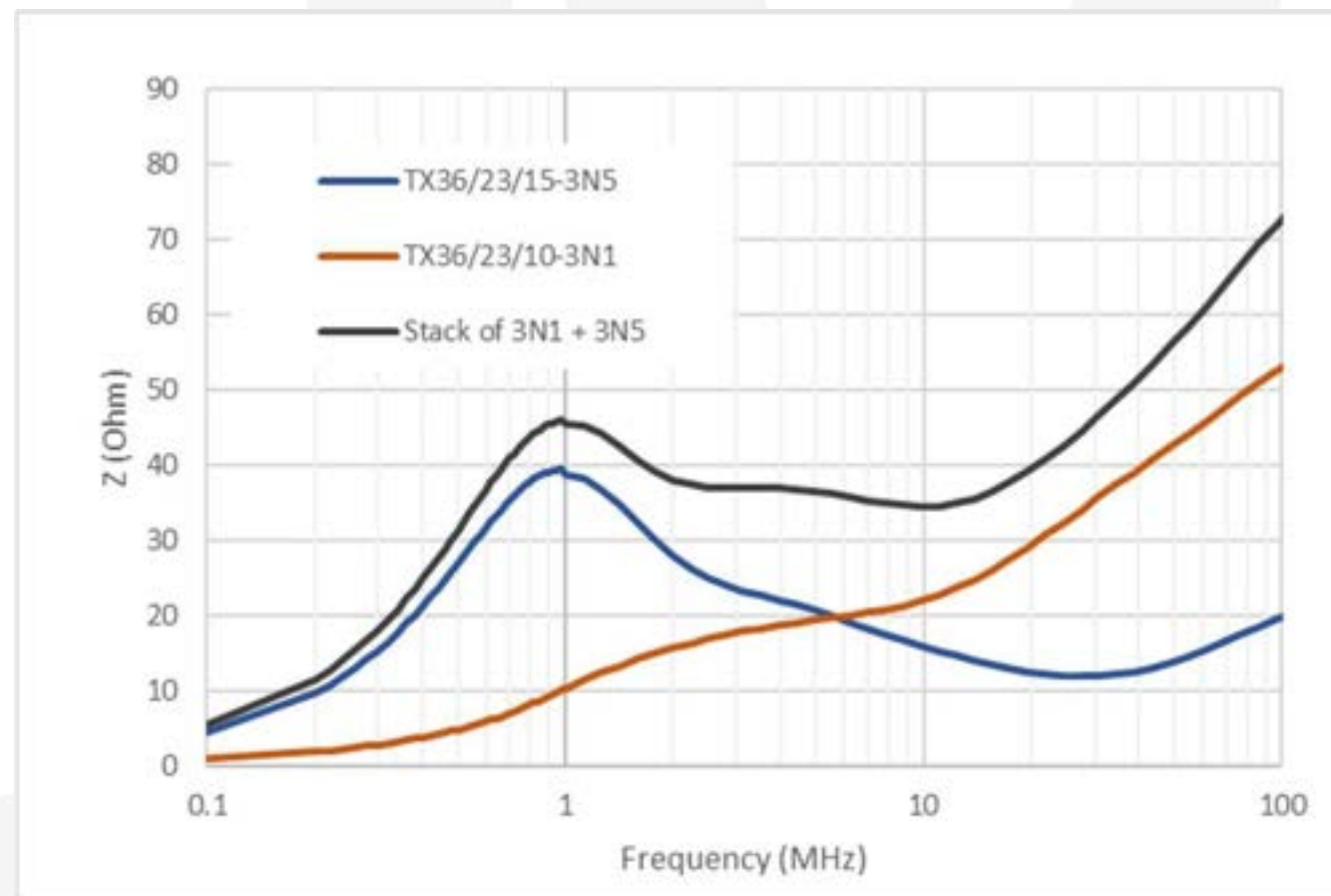
3N5 $\mu_i = 6000$
 $T_c \geq 150^\circ\text{C}$ 0.5-3 MHz

3N10 $\mu_i = 8000$
 $T_c \geq 130^\circ\text{C}$ 0.1-1 MHz



Material stack for Wide Filter

- Full bandwidth EMI filtering can be achieved by stacking 2 materials:
- Low frequency (3N5/3N10) for optimal suppression below 5 MHz
- High frequency (3N1/3N2) for >5 MHz filtering
- Core dimensions can be adjusted to match the ideal Z curve at low and high frequency





4F5 – EMI at high frequency with bias

NiZn wide band EMI suppression 30 to 500 MHz High resistivity

High saturation at high temperature

4F5 SPECIFICATION

Medium permeability NiZn ferrite material suitable for EMI applications, but also recommended for particle acceleration applications with high bias currents at elevated temperatures.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	400±20%	
B	25°C; 10kHz; 1200A/m	≈ 420	mT
	100°C; 10kHz; 1200A/m	≈ 340	
	150°C; 10kHz; 1200A/m	≈ 300	
tand/ μ_i	25°C; 0.1MHz; 0.250mT	≈ 20	10 ⁶
	25°C; 1MHz; 0.250mT	≈ 40	
Z	25°C; 30MHz; 0.250mT	≈ 36	Ω
	25°C; 100MHz; 0.250mT	≈ 72	
DI	0.25mT; 10kHz; 25°C	≈ 2	10 ⁶
ρ_{DC}	25°C	≈ 10 ⁶	Ωm
T _c		≥ 240	°C
density		≈ 5200	kg/m ³

typical parameters measured on T25/15/10

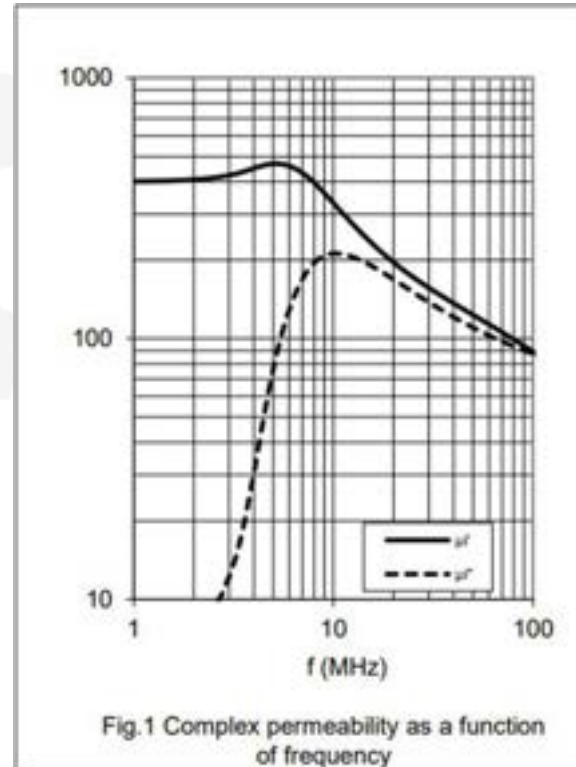


Fig.1 Complex permeability as a function of frequency

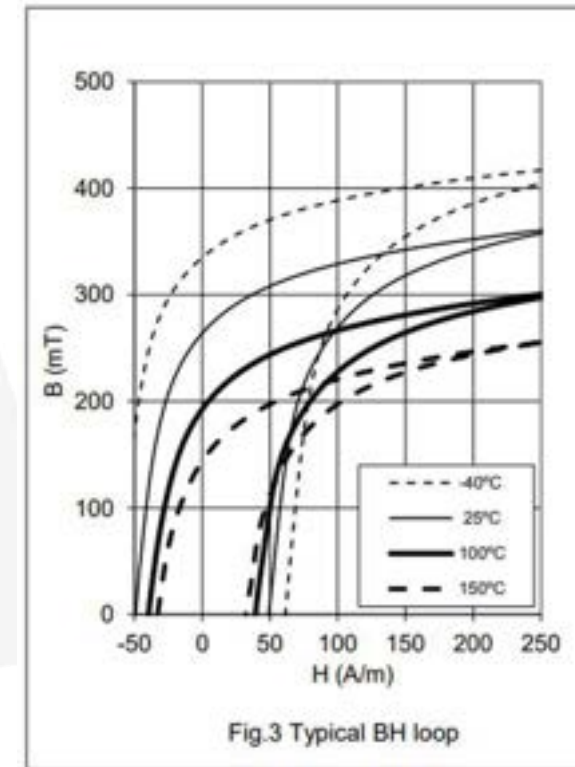


Fig.3 Typical BH loop

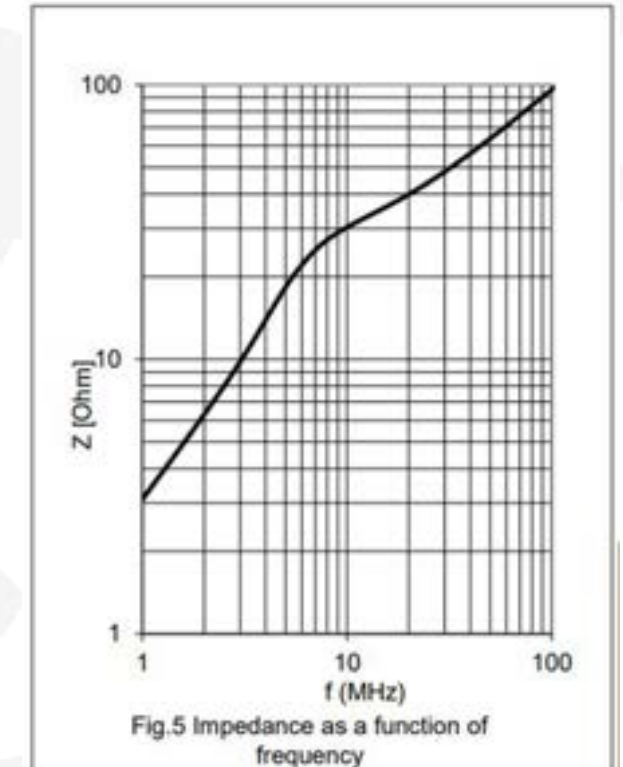


Fig.5 Impedance as a function of frequency

Product Overview

New Technologies

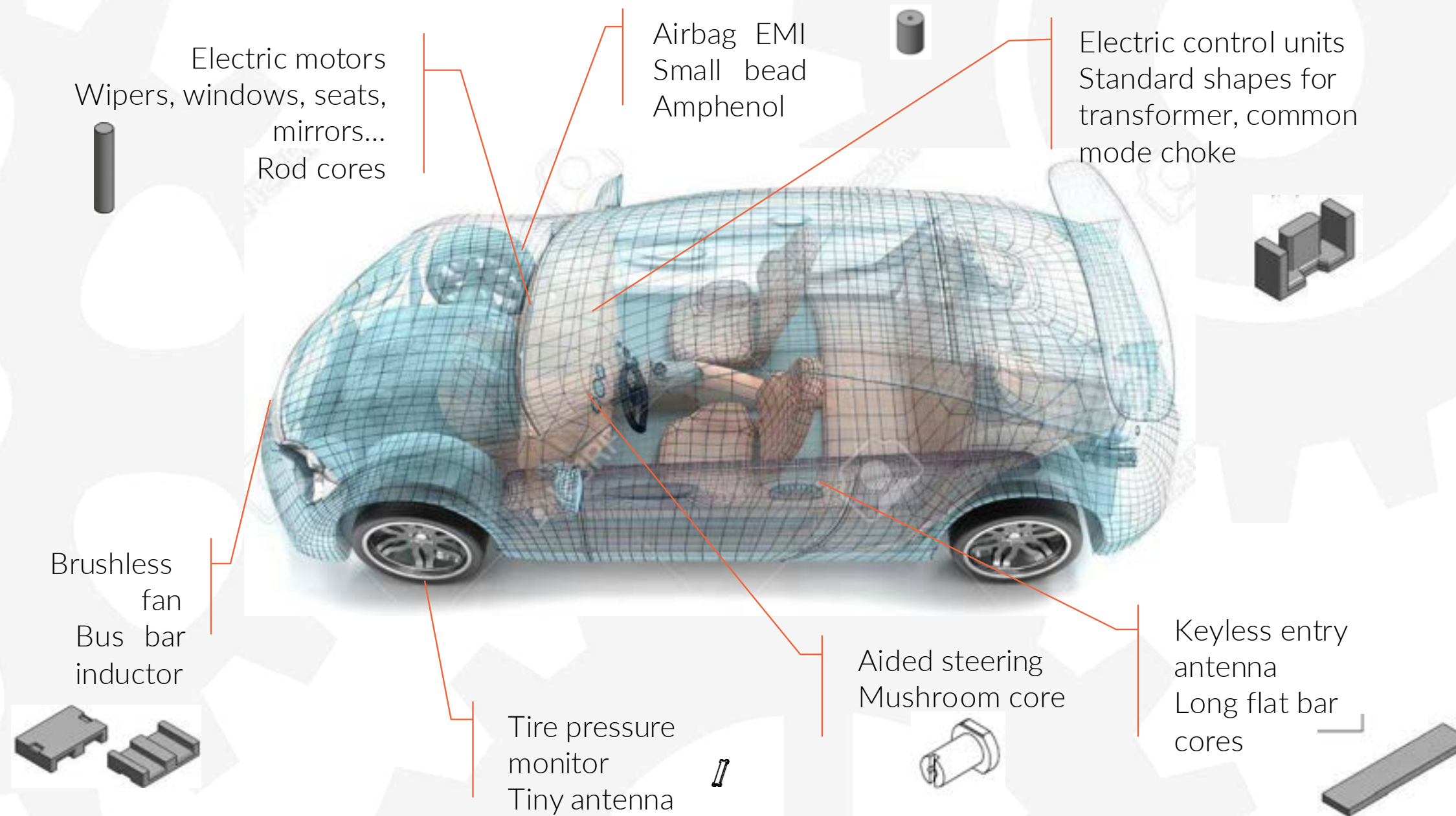
YAGEO GROUP
YAGEO Ferroxcube

THE MAGNETIC
GATEWAY.



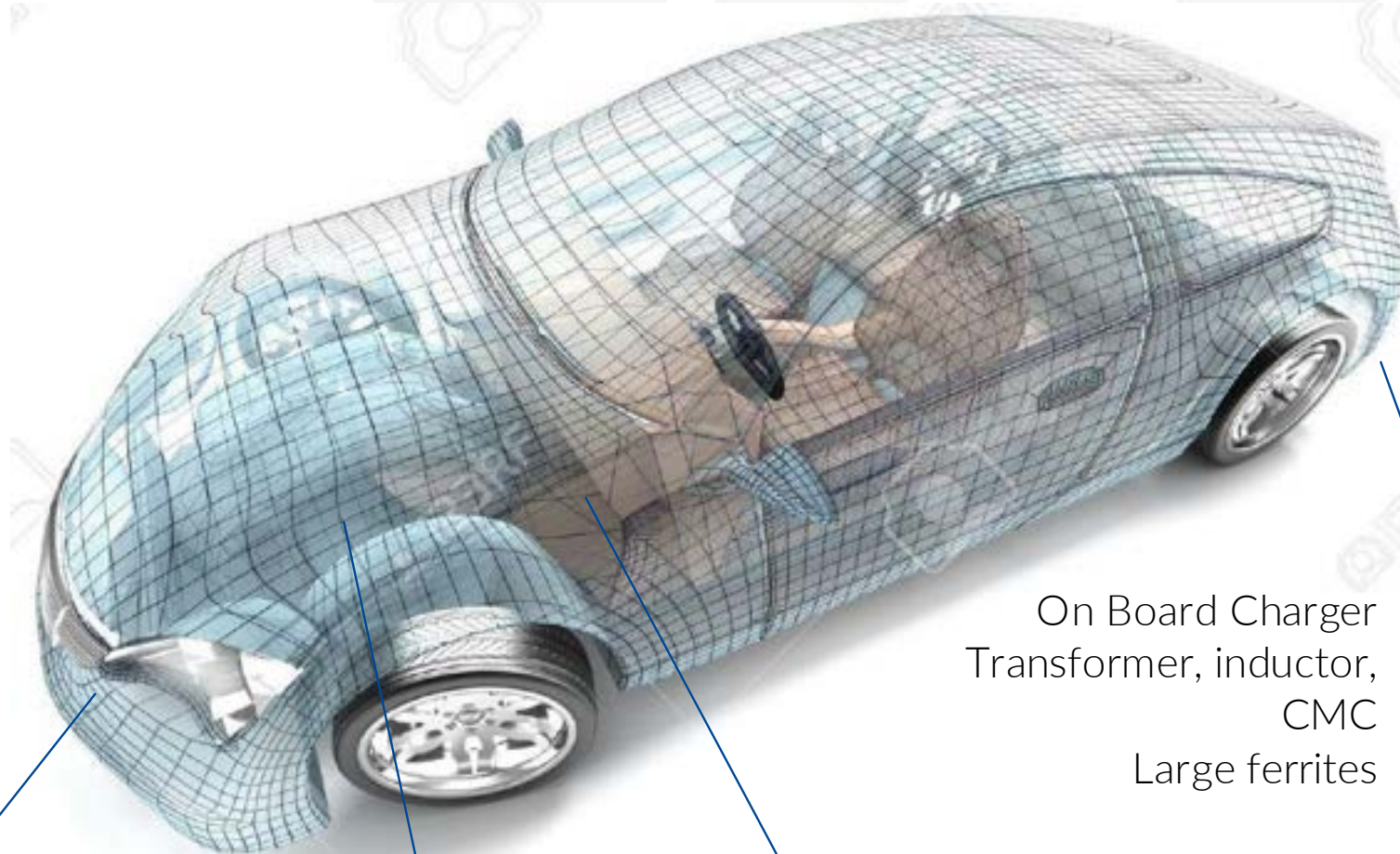
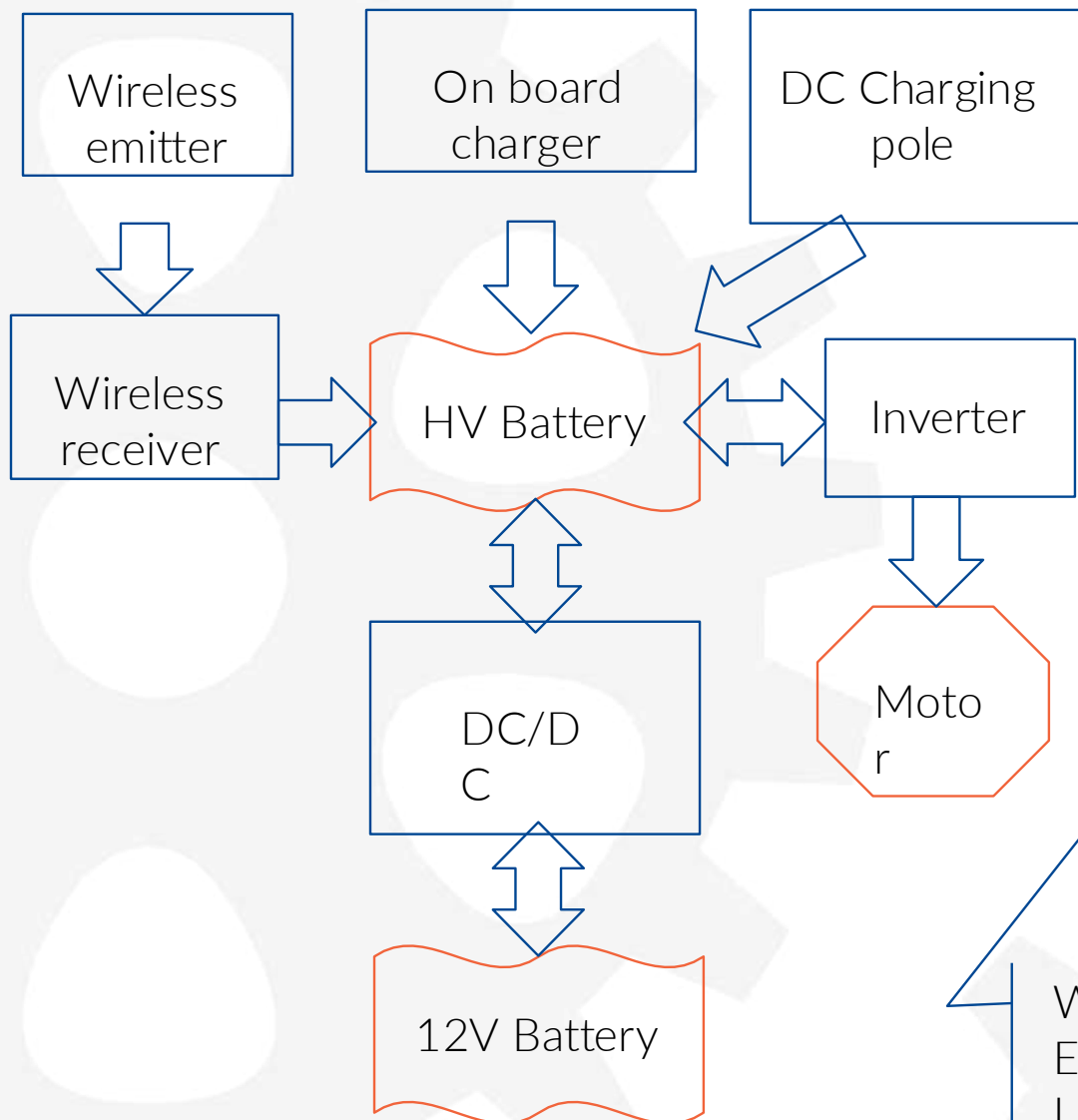


Traditional Automotive Applications





Electric Vehicle Applications



On Board Charger
Transformer, inductor,
CMC
Large ferrites

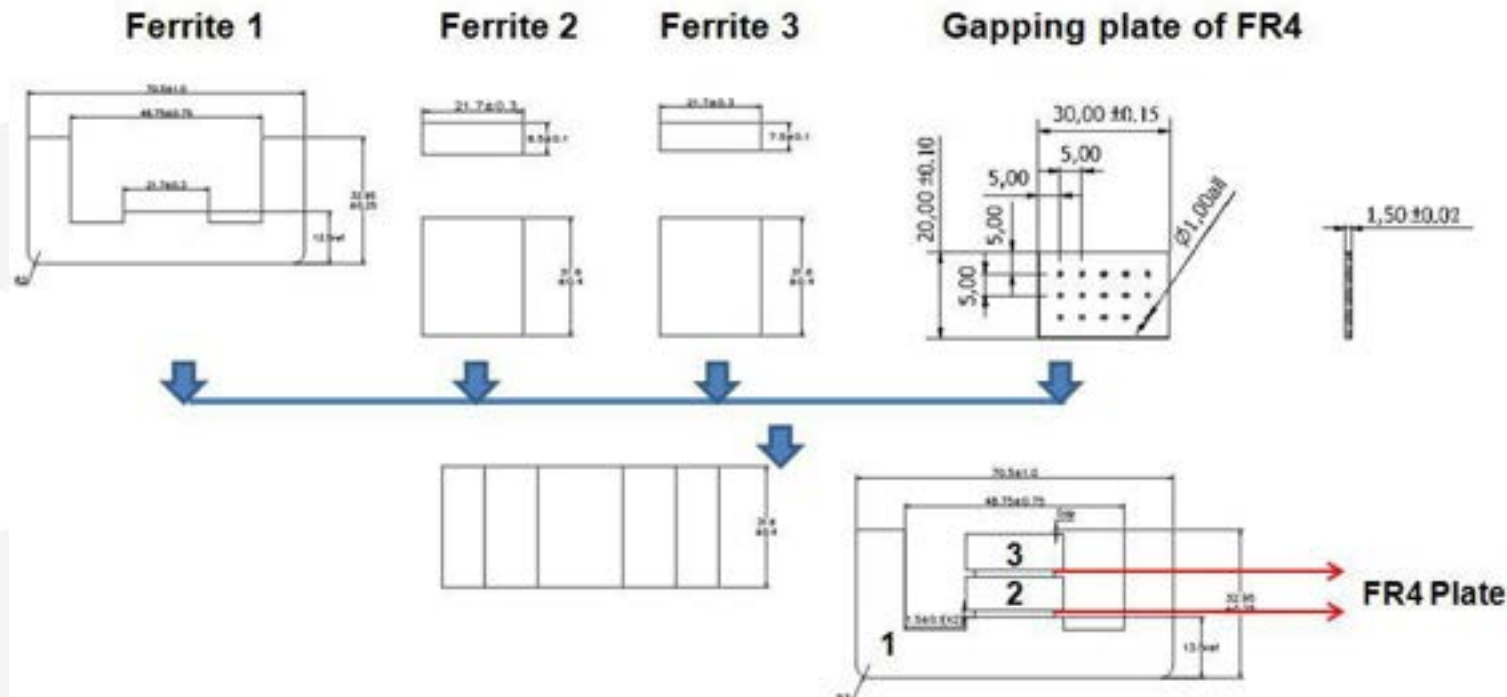
Wireless charger
Emitter and receiver coils
Large ferrite tiles

Inverter
CMC
Large U cores

DC/DC 12V/HV battery
Transformer, inductor, CMC
Mid size and planar cores



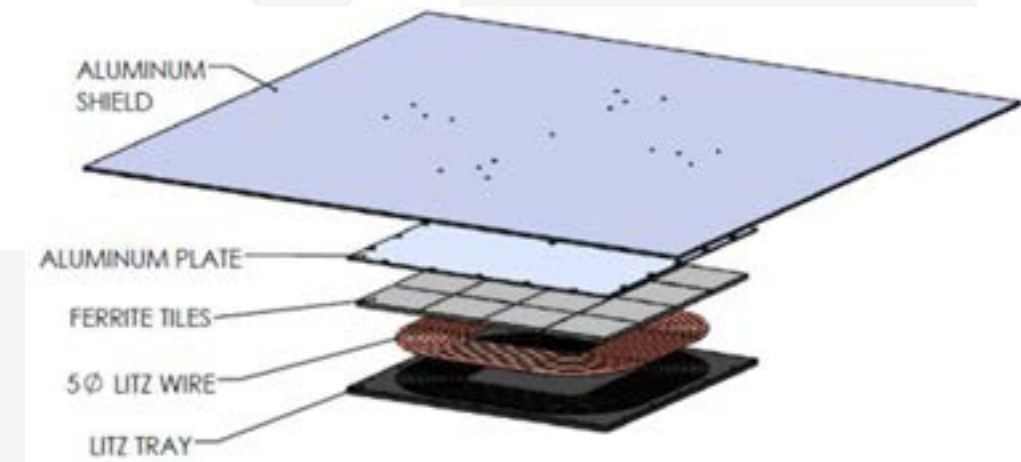
- Distributed air gaps improve the flux density distribution, thus reducing winding losses
- Realized via non-magnetic spacers (Alumina or FR4) glued between the ferrite parts
 - Alumina helps to transfer the heat out of the center leg
 - Customizable spacer thickness
- Other ferrite assemblies available on request



EV Wireless charger ferrite tiles: SAE J2954

- SAE J2954 defines the standard for wireless charger requirements
- Ferroxcube 3C97T exhibits excellent performance, even at high temperature
- Custom sizes available

Surface	Thickness	Ground sides	Ground top/bottom
100 x 100	5 / 10	No	Yes
120 x 120	5 / 10	No	Yes
160 x 86	5 / 10	No	Yes
130 x 130	5 / 10	Yes	Yes
150 x 100	5 / 10	Yes	Yes
100 x 100	5 / 10	Yes	Yes
50 x 50	5 / 10	Yes	Yes



Both factories ISO14001, ISO9001 and IATF certified
Released by several Tier 1 suppliers (Valeo, Bosch, Borg Warner...)





Custom packaging for cleanliness and automation

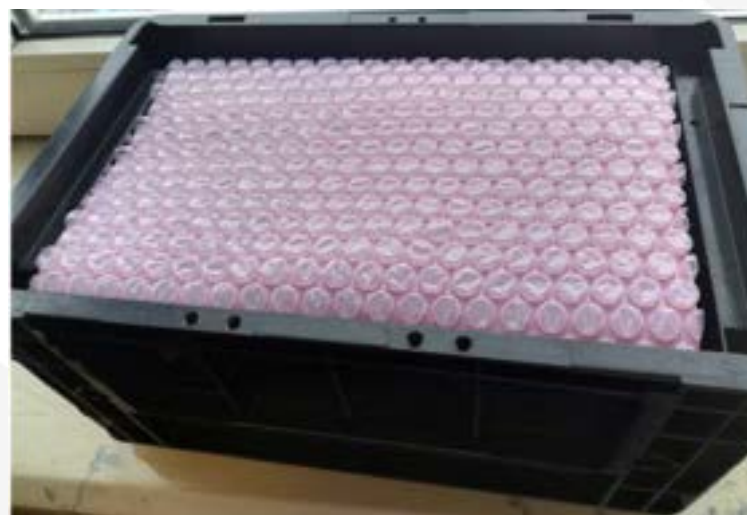
Returnable

- PET ESD tray, returnable
- KLT box, returnable
- Handling unit, returnable
- Plastic pallet, returnable



Disposable

- EPE tray stack: best for protection
- PET tray stack: best for automation
- Double plastic bag
- Carton box
- Wooden pallet



In house testing: environmental (AEC-Q200)



Temperature / Humidity test chamber



Thermo-cycle
test chamber



In house testing: cleanliness



Sample extraction chamber



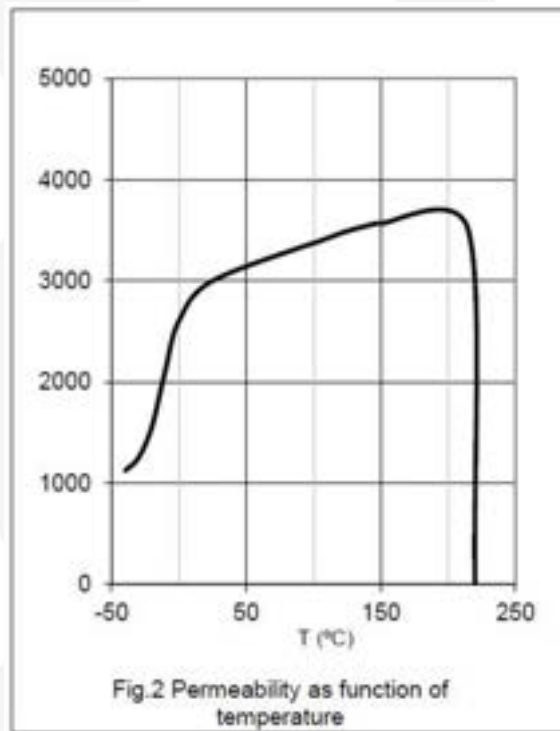
Microscope with software
and report function



3C97 – Premium material for power conversion

Optimized for 50 – 400 kHz

Flat response 50 to 140 °C

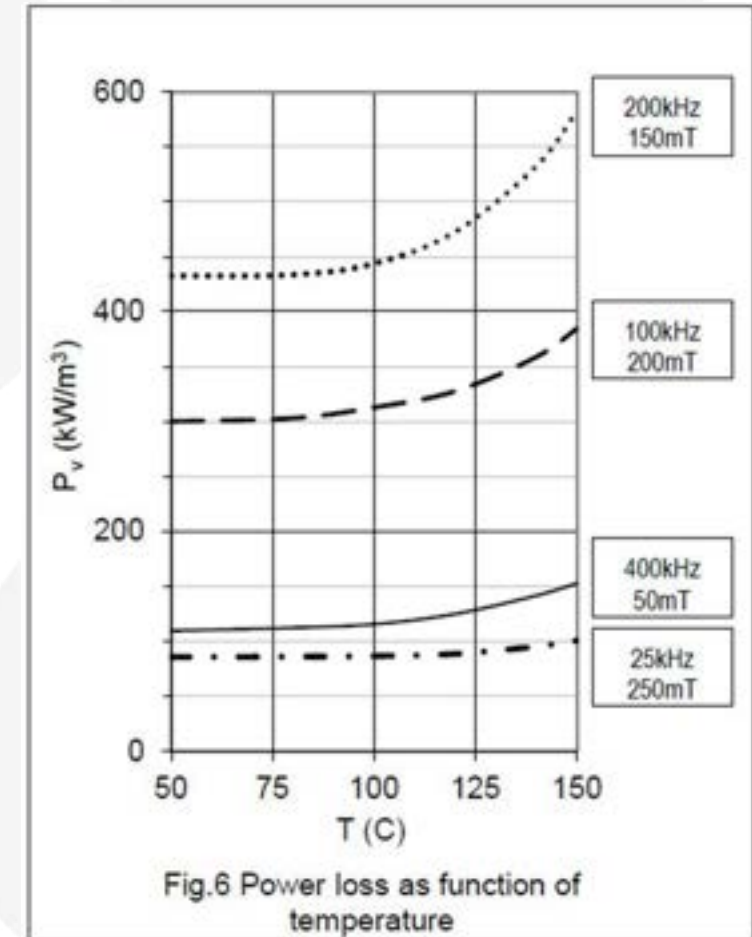


3C97 SPECIFICATION

A low to medium frequency power material with low power losses from 50 to 150 °C. For use in power and general purpose transformers at frequencies up to 0.5MHz. Material should not be exposed to temperatures exceeding 150°C for long time.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	$3000 \pm 25\%$	
μ_a	25°C; 25kHz; 200mT	≈ 5000	
B	25°C; 10kHz; 1200A/m	≈ 550	mT
	100°C; 10kHz; 1200A/m	≈ 430	
	140°C; 10kHz; 1200A/m	≈ 360	
P _v	60°C; 100kHz; 200mT	≈ 320	kW / m ³
	140°C; 100kHz; 200mT	≈ 380	
ρ_{DC}	25°C	≈ 10	Ωm
T _c		≥ 215	°C
density		≈ 4850	kg / m ³

Typical performance of unstressed ring T25/15/12



3C97T – Lowest losses over temperature

Lowest losses in the range 25 to 100°C

Optimized operation up to 300 kHz thanks to high resistivity

R&D!

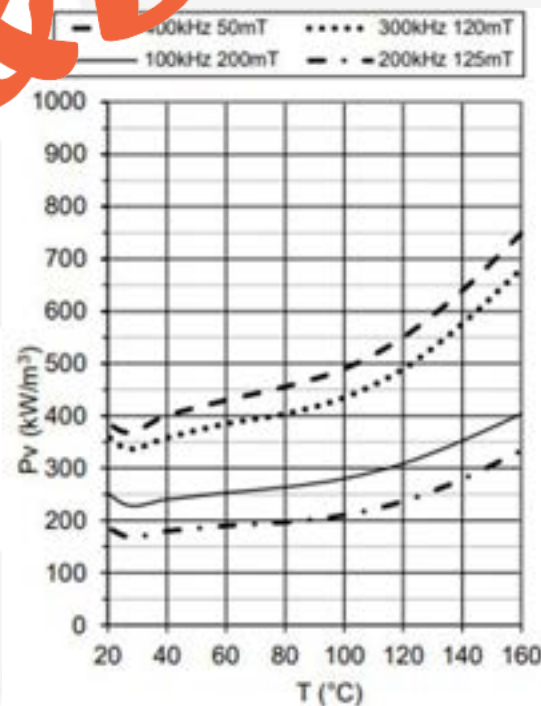


Fig.5 Power loss as a function of Temperature

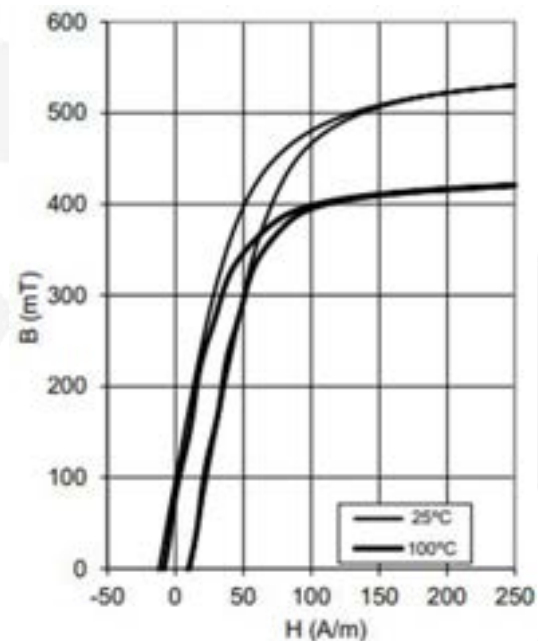


Fig.3 Typical BH loops

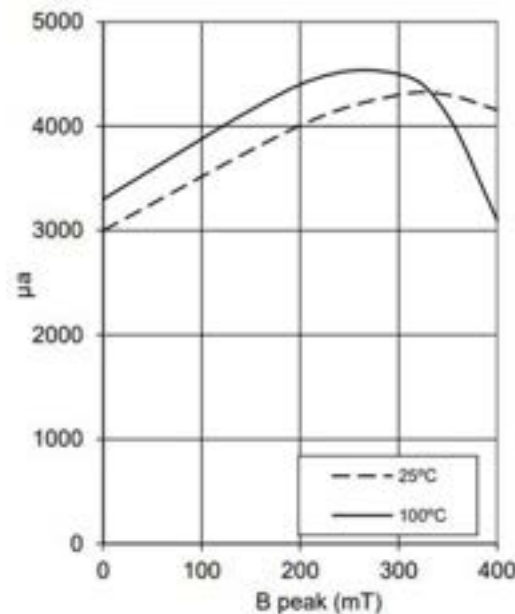


Fig.4 Amplitude permeability

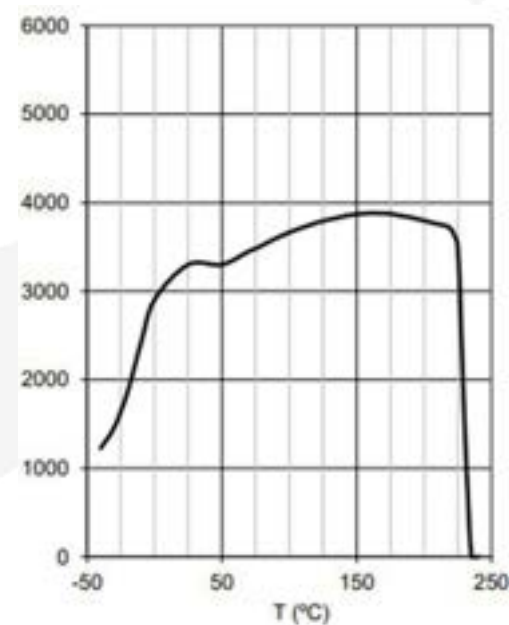


Fig.2 Permeability as a function of temperature

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	3300 ± 25%	
μ_a	100°C; 25kHz; 200mT	≈ 4500	
B	25°C; 10kHz; 1200A/m	≈ 550	mT
	100°C; 10kHz; 1200A/m	≈ 435	
Pv	25°C; 100kHz; 200mT	≈ 230	kW / m ³
	60°C; 100kHz; 200mT	≈ 235	
	80°C; 100kHz; 200mT	≈ 245	
	100°C; 100kHz; 200mT	≈ 280	
	120°C; 100kHz; 200mT	≈ 320	
	140°C; 100kHz; 200mT	≈ 380	
Pv	25°C; 200kHz; 125mT	≈ 185	kW / m ³
	60°C; 200kHz; 125mT	≈ 180	
	80°C; 200kHz; 125mT	≈ 185	
	100°C; 200kHz; 125mT	≈ 210	
	120°C; 200kHz; 125mT	≈ 260	
	140°C; 200kHz; 125mT	≈ 320	
Pv	25°C; 300kHz; 120mT	≈ 355	kW / m ³
	60°C; 300kHz; 120mT	≈ 375	
	80°C; 300kHz; 120mT	≈ 395	
	100°C; 300kHz; 120mT	≈ 435	
	120°C; 300kHz; 120mT	≈ 520	
Pv	25°C; 400kHz; 100mT	≈ 415	kW / m ³
	60°C; 400kHz; 100mT	≈ 430	
	80°C; 400kHz; 100mT	≈ 445	
	100°C; 400kHz; 100mT	≈ 490	
	120°C; 400kHz; 100mT	≈ 600	
pDC	25°C	≈ 15	Ωm
Tc		≥ 230	°C
density		≈ 4850	kg / m ³



3C95F – Premium material for power conversion

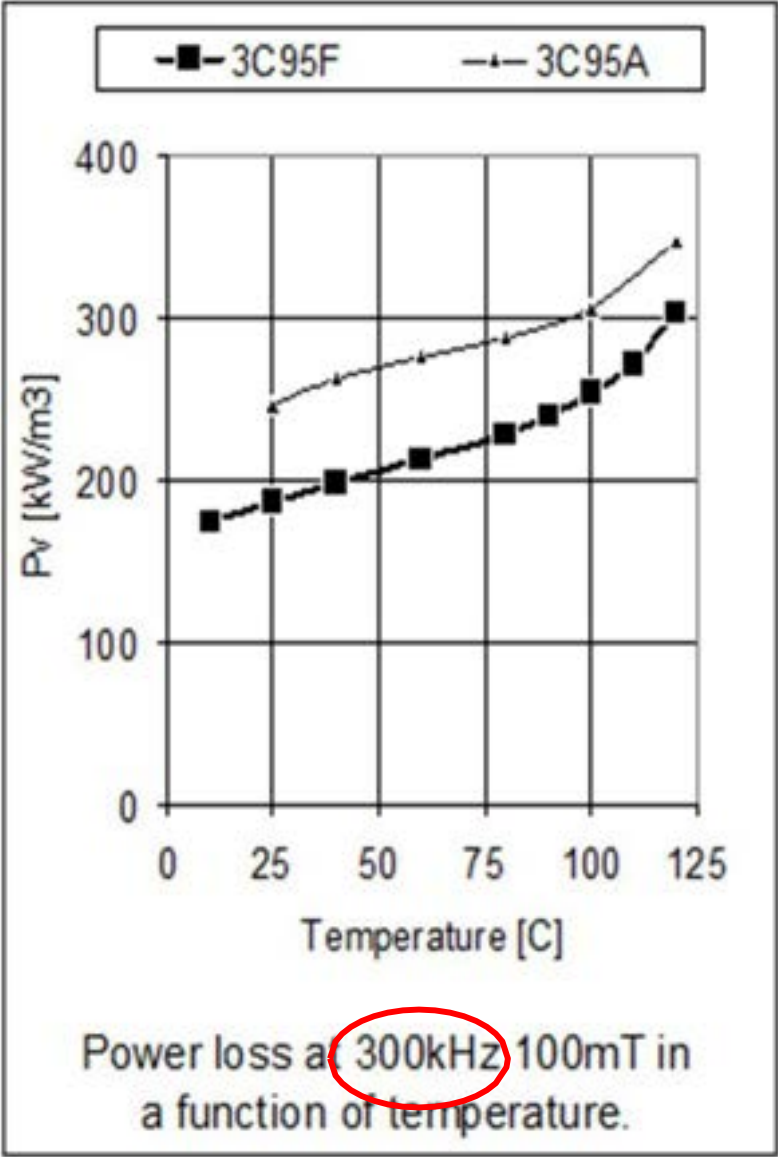


Optimized for 200 - 400 kHz

Flat response 0 to 100 °C

High Bsat

CONDITIONS		UNIT	3C95F	3C95A
μ_i	25°C; 10kHz; 0.25mT		3000 ± 20%	3300 ± 20%
μ_a	100°C; 25kHz; 200mT		≈ 4500	≈ 5000
B	25°C; 10kHz; 1200A/m	mT	≈ 550	≈ 550
	100°C; 10kHz; 200A/m		≈ 430	≈ 430
Pv	100°C; 100kHz; 200mT	kW/m³	≈ 310*	≈ 290
	100°C; 200kHz ; 125mT		≈ 250	≈ 400*
	100°C; 300kHz ; 100mT		≈ 270	≈ 350*
ρ_{DC}	25°C	Ωm	≈ 10	≈ 10
Tc		°C	≥ 210	≥ 210
density		kg/m³	≈ 4850	≈ 4850



3C91A – Low temperature power conversion

Up to 300 kHz

Flat in 0 – 60 °C temperature range

Highest μ_i and μ_a

High Bsat at low temperature

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	3200 ± 25%	
μ_a	100°C; 25kHz; 200mT	≈ 4800	
B	25°C; 10kHz; 1200A/m	≈ 530	mT
	100°C; 10kHz; 1200A/m	≈ 410	
Pv	25°C; 100kHz; 200mT	≈ 250	k W / m ³
	60°C; 100kHz; 200mT	≈ 260	
ρ_{DC}	25°C	≈ 5	Ωm
Tc		≥ 215	°C
density		≈ 4850	k g / m ³

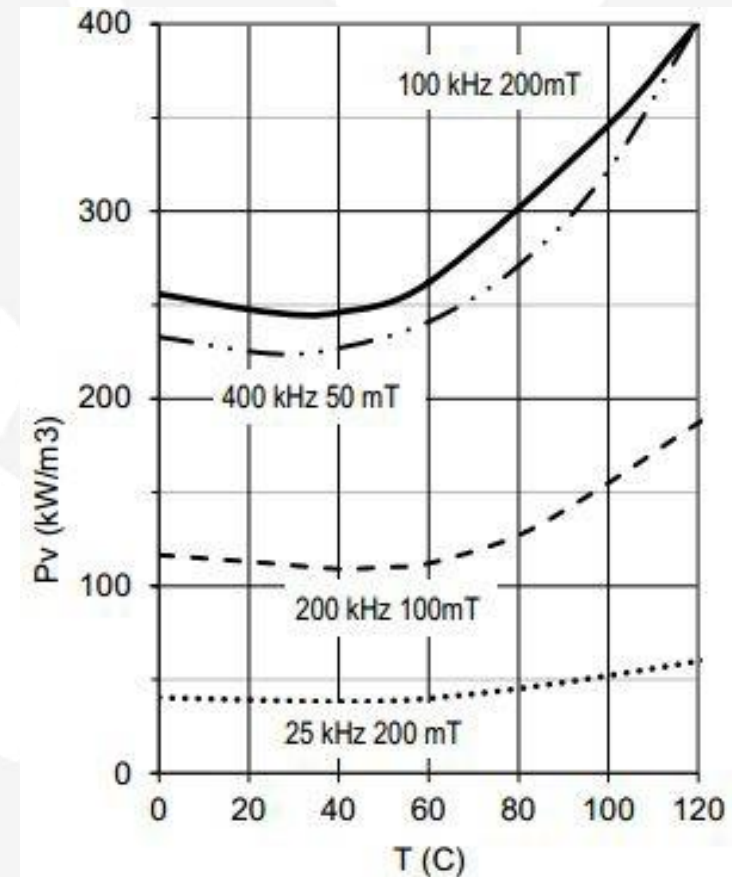


Fig.6 Power loss as function of Temperature



3C97A – Power conversion at high temperature

Minimum loss at 160 °C

High and stable saturation below 160 °C

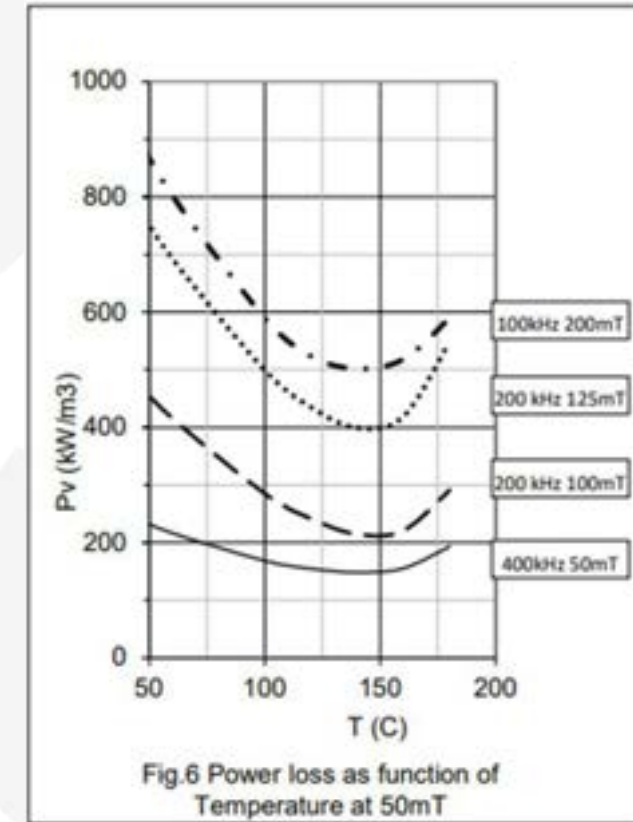
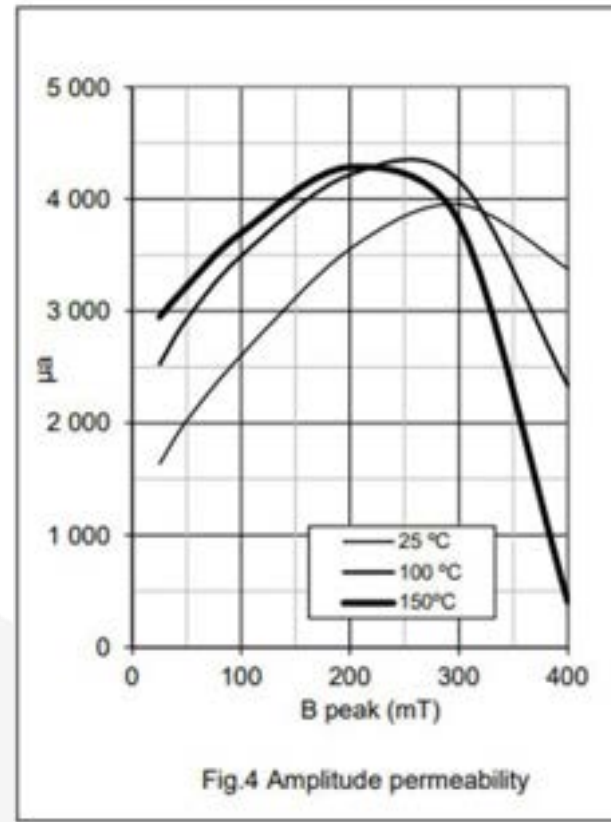
New!

3C97A SPECIFICATION

A medium frequency, high temperature power material with minimum power losses at 140 - 160°C for use in power and general purpose transformers.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	1100 $\pm$ 25%	
μ_a	25°C; 25kHz; 200mT	$\approx$ 4000	
B	25°C; 10kHz; 1200A/m	$\approx$ 520	mT
	100°C; 10kHz; 1200A/m	$\approx$ 440	
	150°C; 10kHz; 1200A/m	$\approx$ 370	
Pv	100, 150°C; 100kHz; 200mT	$\approx$ 500	kW/m ³
	100, 150°C; 200kHz; 125mT	$\approx$ 400	
	100, 150°C; 400kHz; 50mT	$\approx$ 150	
ρ_{DC}	25°C	$\approx$ 8	Ω m
Tc		$\geq$ 280	°C
density		$\approx$ 4800	kg/m ³

Typical performance of unstressed ring T25/15/12





3C99 – Power conversion at 200 C

Decreasing losses up to 200C

Ideal to prevent thermal runaway

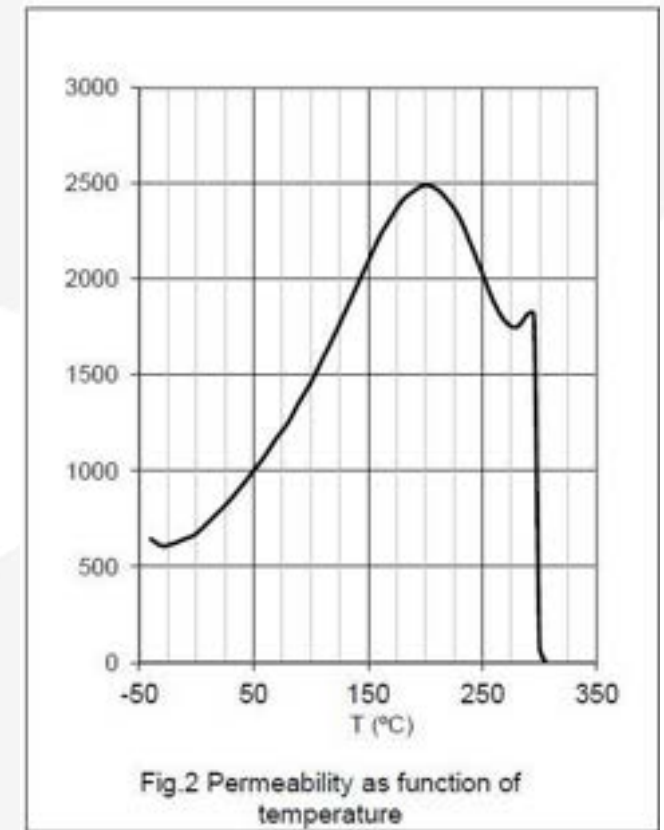
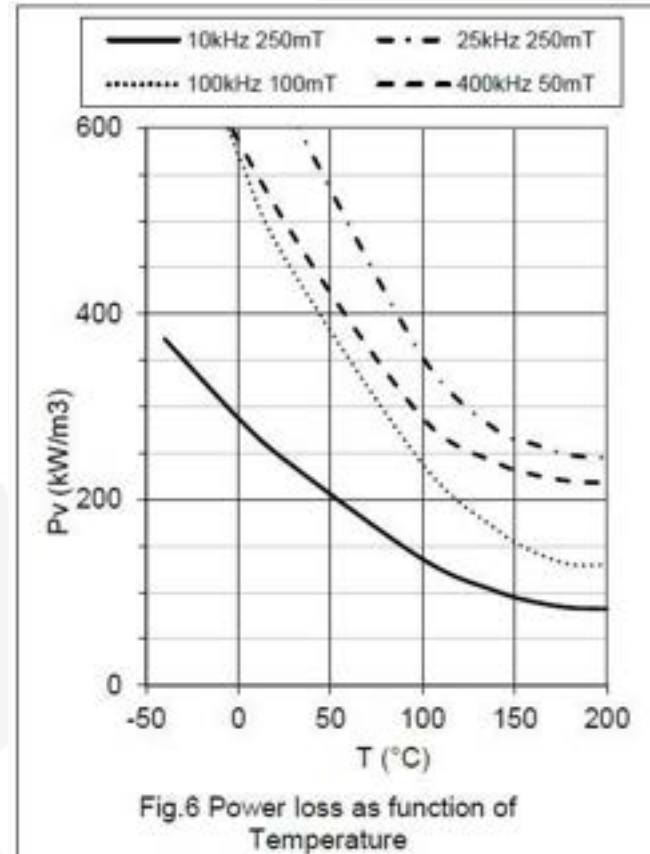
Frequency range 50 to 400 kHz

New!

3C99 SPECIFICATION

A medium frequency power material with high Curie temperature, optimized for 200°C working temperature.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	$800 \pm 20\%$	
μ_a	200°C; 10kHz; 200mT	≈ 4000	
B	25°C; 10kHz; 1200A/m	≈ 500	mT
	100°C; 10kHz; 1200A/m	≈ 450	
	200°C; 10kHz; 1200A/m	≈ 320	
P _v	200°C; 25kHz; 200mT	≈ 140	kW / m ³
	200°C; 100kHz; 100mT	≈ 140	
	200°C; 400kHz; 50mT	≈ 220	
ρ_{DC}	25°C	≈ 6	Ωm
T _c		≥ 300	°C
density		≈ 4800	kg / m ³





3F36 – Flat response below 1 MHz

Optimum material for 400 kHz to 1 MHz

Flat power loss and permeability 25 to 100 C

High resistivity, ideal for large cores

CONDITIONS		UNIT	3F36
μ_i	25°C; 10kHz; 0.25mT		1600 ± 20%
μ_a	100°C; 25kHz; 200mT		≈ 2400
B	25°C; 10kHz; 1200A/m	mT	≈ 520
	100°C; 10kHz; 1200A/m		≈ 420
Pv	100°C; 400kHz; 50mT	kW/m ³	≈ 50
	100°C; 500kHz; 50mT		≈ 90
	100°C; 500kHz ; 100mT		≈ 700
ρ_{DC}	25°C	Ωm	≈ 12
Tc		°C	≥ 230
density		kg/m ³	≈ 4750

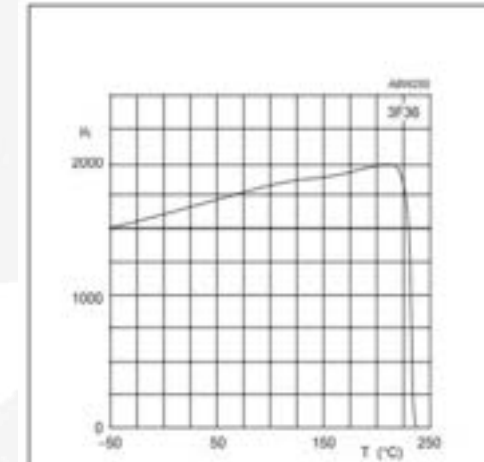


Fig.2 Initial permeability as a function of temperature.

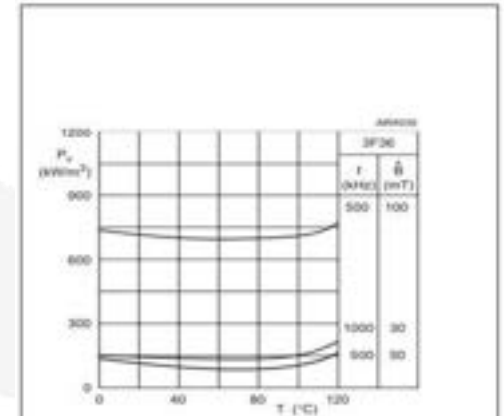


Fig.7 Specific power loss for several frequency/flux density combinations as a function of temperature.

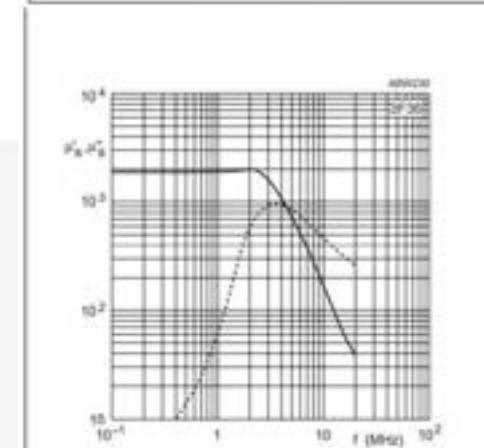


Fig.1 Complex permeability as a function of frequency.

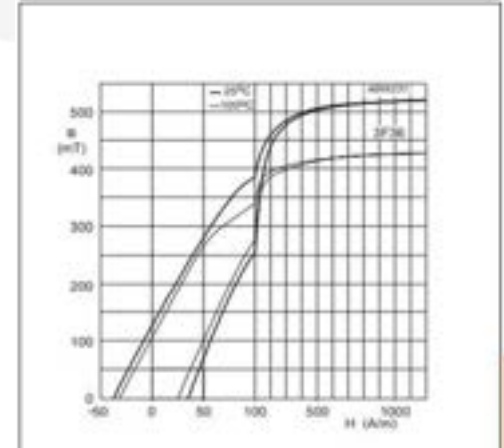


Fig.3 Typical B-H loops.

3F36P – Power inductors at high frequency

Low loss at low temperature

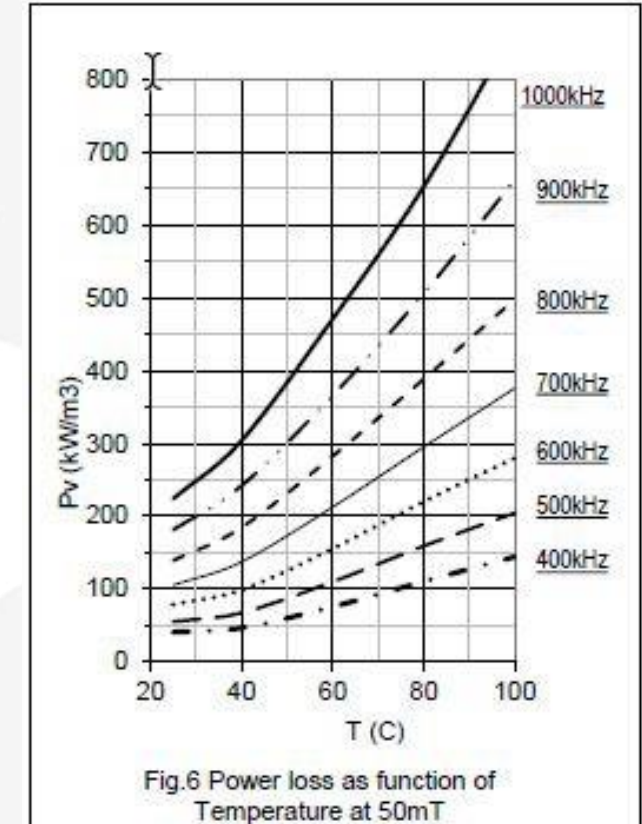
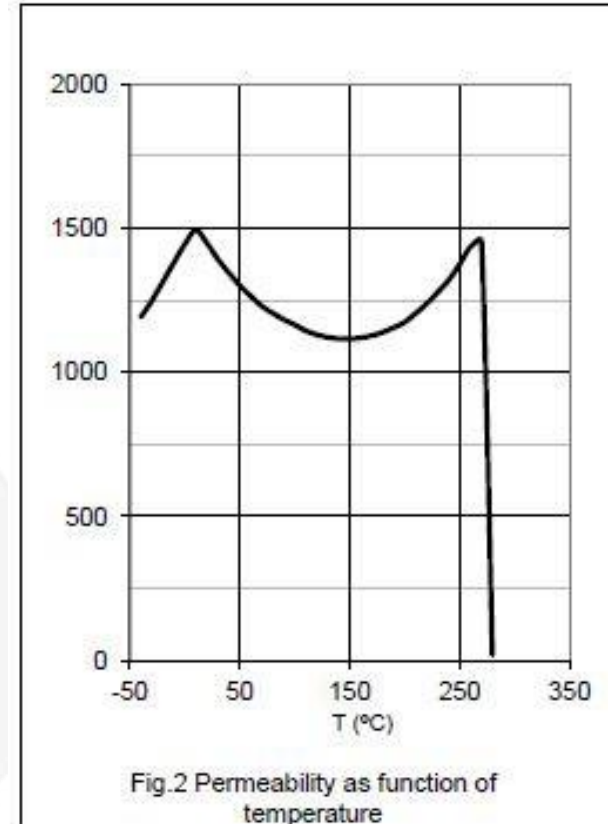
Optimized for 400 to 1000

kHz Highest Bsat

3F36P SPECIFICATION

A high frequency power material optimized for low loss with high DC signal for use in power inductors.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	$1400 \pm 25\%$	
μ_a	25°C; 25kHz; 200mT	≈ 1800	
B	25°C; 10kHz; 1200A/m	≈ 550	mT
	100°C; 10kHz; 1200A/m	≈ 450	
P _v	25°C; 500MHz; 50mT	≈ 50	kW / m ³
	25°C; 1MHz; 50mT	≈ 225	
ρ_{DC}	25°C	≈ 6	Ωm
T _c		≥ 270	°C
density		≈ 4.75	kg / m ³





3F46 – Power conversion beyond 1 MHz

Optimum performance 1 to 3 MHz

Flat response with high Bsat Small

and mid size

A high frequency power material for use in power and general purpose transformers at frequencies of 1-3MHz. Temperature characteristic tuned for stable operation in range 25-100°C. Available in product size up to 40mm.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	$750 \pm 20\%$	
μ_a	100°C; 25kHz; 200mT	≈ 1500	
B	25°C; 10kHz; 1200A/m	≈ 520	mT
	100°C; 10kHz; 1200A/m	≈ 430	
Pv	100°C; 1MHz; 50mT	≈ 150	mW/cm ³
	100°C; 3MHz; 10mT	≈ 50	
	100°C; 3MHz; 30mT	≈ 500	
ρ_{DC}	25°C	≈ 5	Ωm
Tc		≥ 280	°C
density		≈ 4750	kg / m ³

based on T14/9/5

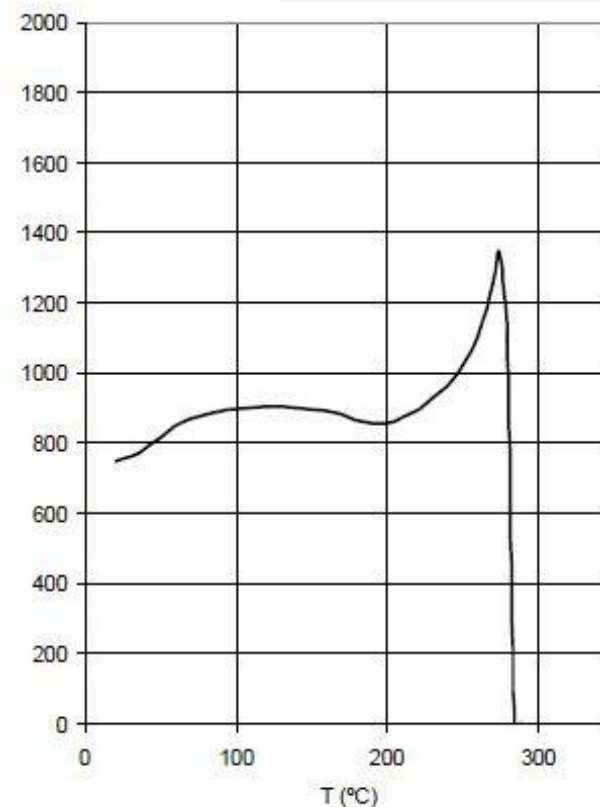


Fig.2 Permeability as a function of temperature

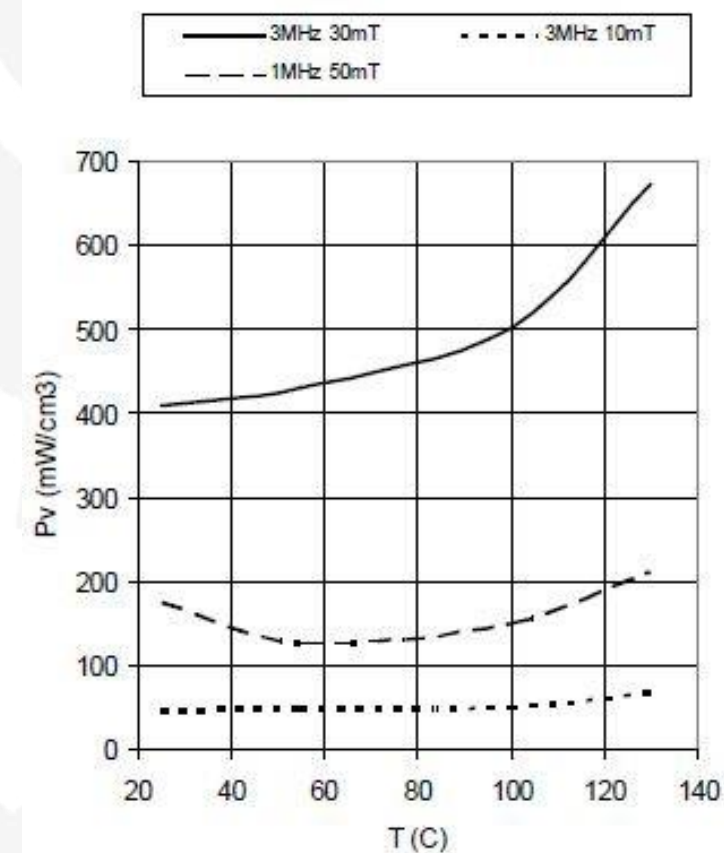


Fig.6 Power loss as a function of temperature



3F46A – Lowest power loss beyond 1 MHz

Optimized 1 to 3 MHz Lowest power loss
Small and mid size

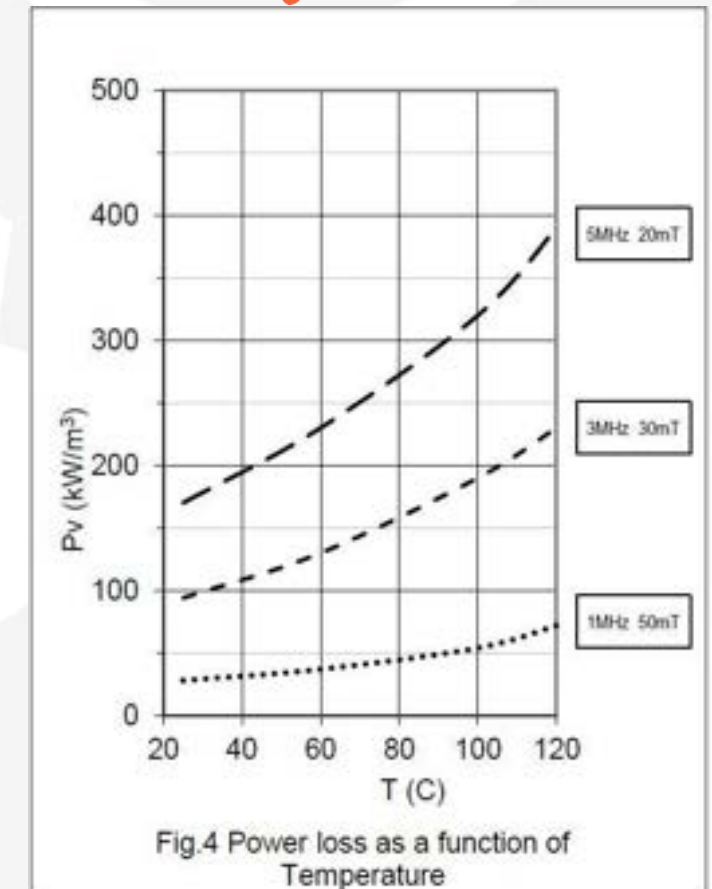
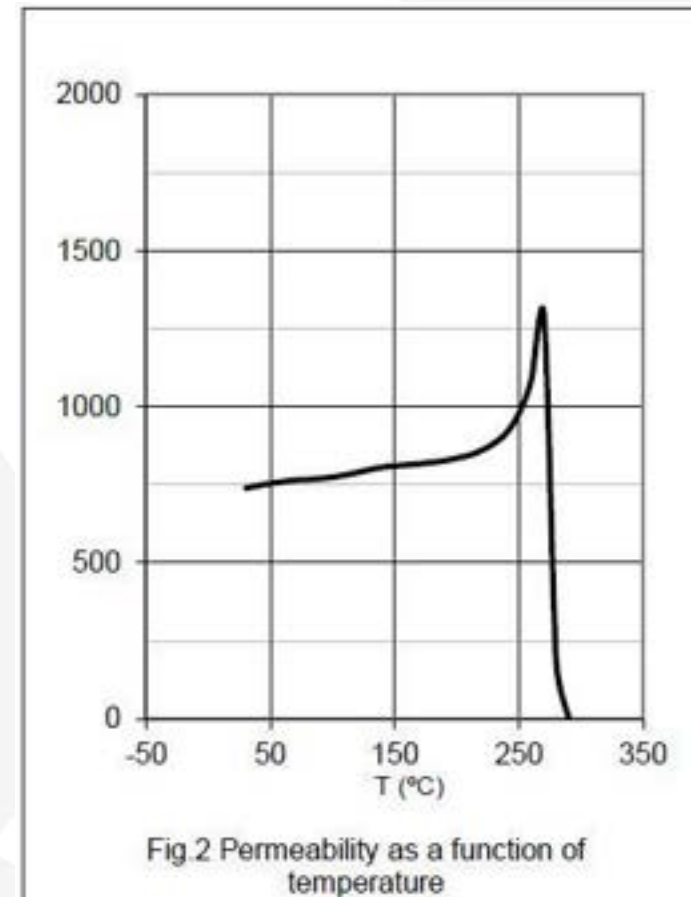
R&D!

3F46A SPECIFICATION

A high frequency power material for use in power and general purpose transformers at frequencies of 1-5 MHz. For best performance, saturation should be avoided. Available in product size up to 40 mm.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	$750 \pm 25\%$	
μ_a	100°C; 25kHz; 200mT	≈ 1400	
B	25°C; 10kHz; 1200A/m	≈ 540	mT
	100°C; 10kHz; 1200A/m	≈ 440	
P _v	25°C; 1MHz; 50mT	≈ 70	kW/m ³
	100°C; 1MHz; 50mT	≈ 100	
	25°C; 3MHz; 30mT	≈ 200	
	100°C; 3MHz; 30mT	≈ 300	
	25°C; 5MHz; 20mT	≈ 200	
	100°C; 5MHz; 20mT	≈ 360	
ρ_{DC}	25°C	≈ 5	Ωm
T _c		≥ 270	°C
density		≈ 4750	kg / m ³

Typical performance of T14/9/5





3F56 – Power conversion 3 to 5 MHz

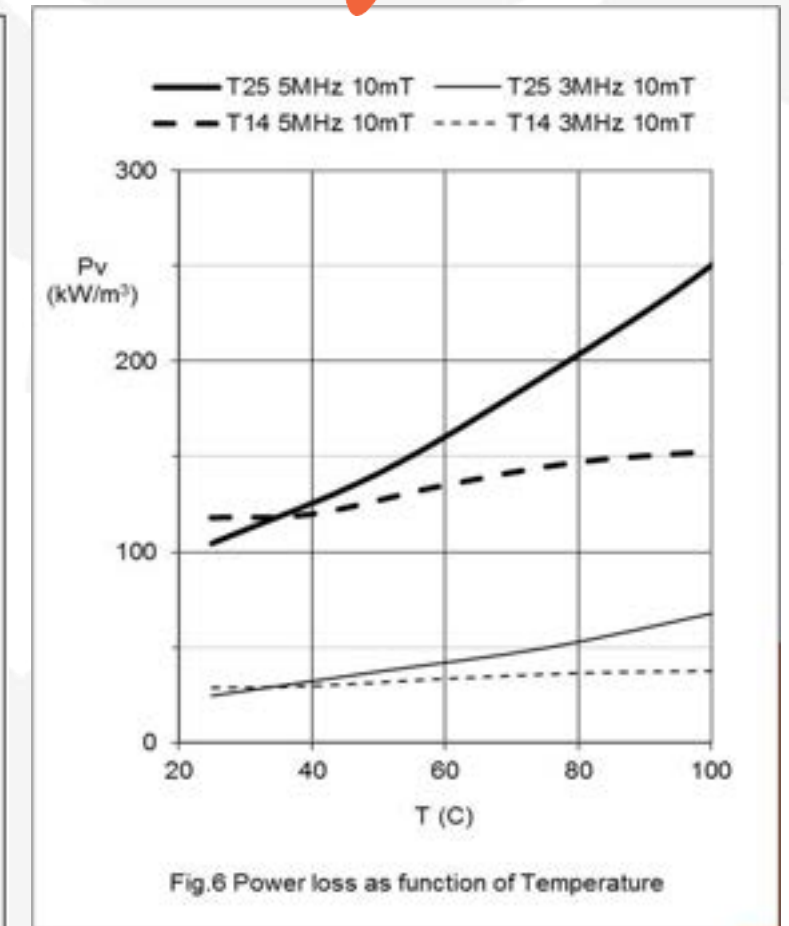
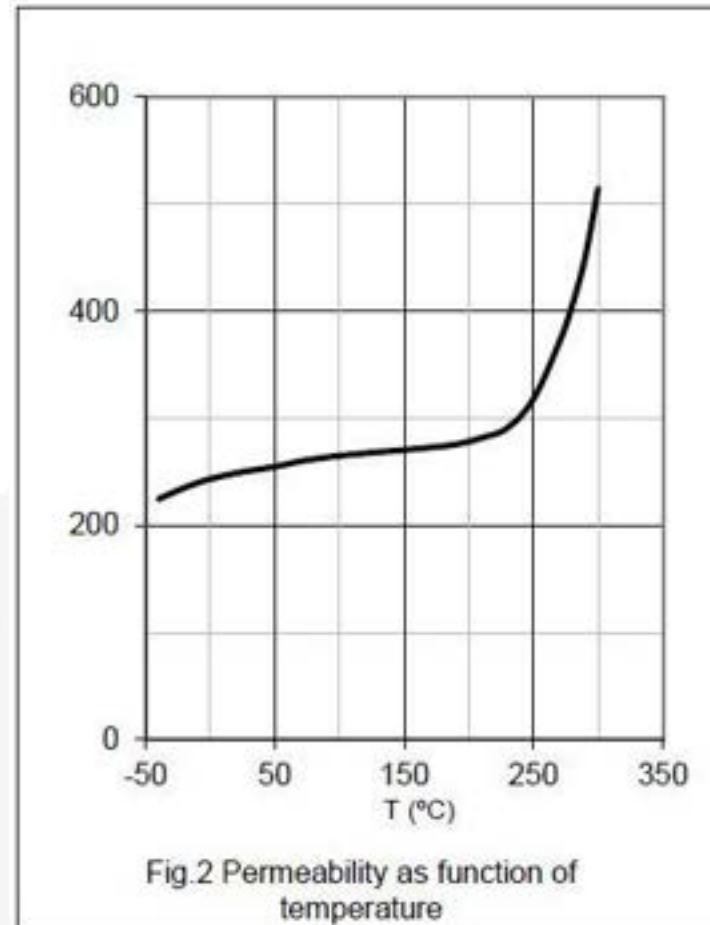
Highest frequency MnZn material
Flat response with stable Bsat over temp
Very high Tc
Compared to NiZn:
Higher Bsat
Higher Permeability
Lower loss

R&D!

3F56 SPECIFICATION

A high frequency power material with flat permeability, optimized for 3MHz, 30mT up to 5 MHz, 15mT. For best performance, saturation should be avoided.

SYMBOL	CONDITIONS	T25/15/12	T14/9/5	UNIT
μ_i	25°C; 10kHz; 0.25mT	250 $\pm$ 25%		
μ_a	25°C; 25kHz; 200mT	$\approx$ 750		
B	25°C; 10kHz; 1200A/m 100°C; 10kHz; 1200A/m	$\approx$ 500 $\approx$ 440		mT
Pv	100°C; 3MHz; 10mT 100°C; 5MHz; 10mT	$\approx$ 70 $\approx$ 250	$\approx$ 40 $\approx$ 150	k W / m ³
ρ_{DC}	25°C	$\approx$ 5		Ω m
Tc		$\geq$ 300		°C
density		$\approx$ 4700		k g / m ³





4F1 – Power conversion below 15 MHz

High resistivity NiZn material

Ideal for operation at 13.56 MHz

4F1 SPECIFICATIONS

A very high frequency NiZn power material for use in power and general purpose transformers optimized for frequencies of 4 - 10 MHz.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25 °C; ≤ 10 kHz; 0.25 mT	= 80	
μ_a	100 °C; 25 kHz; 200 mT	= 300	
B	25 °C; 10 kHz; 3000 A/m 100 °C; 10 kHz; 3000 A/m	= 320 = 260	mT
P_v	100 °C; 3 MHz; 10 mT 100 °C; 10 MHz; 5 mT	≤ 200 ≤ 200	kW/m ³
ρ	DC; 25 °C	= 10^5	Ω m
T_c		≥ 260	°C
density		= 4600	kg/m ³

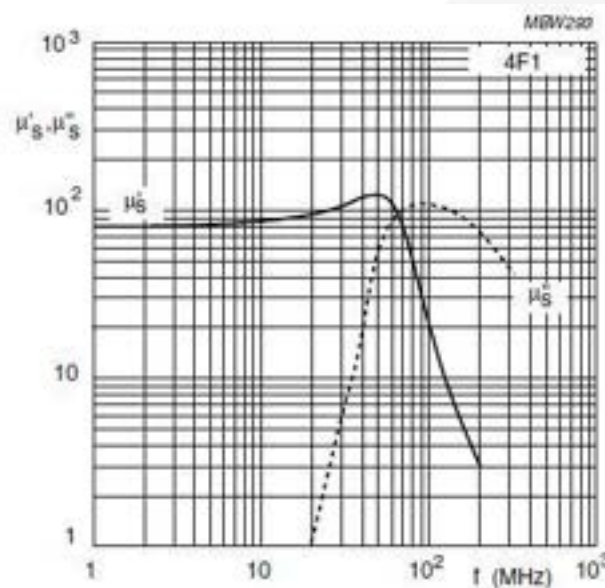


Fig.1 Complex permeability as a function of frequency.

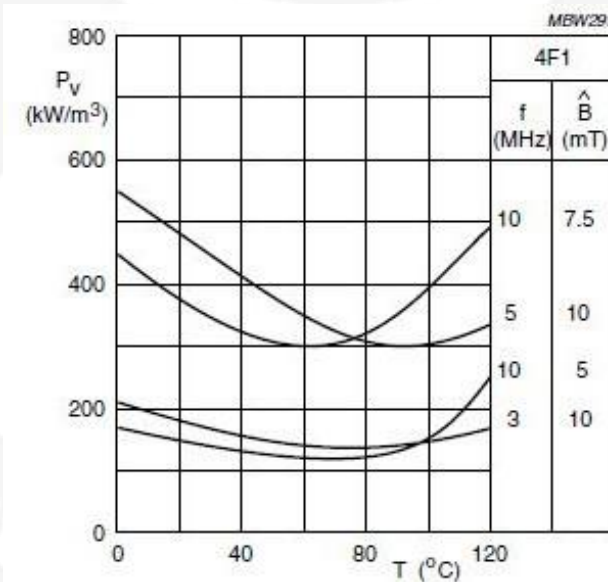


Fig.7 Specific power loss for several frequency/flux density combinations as a function of temperature.



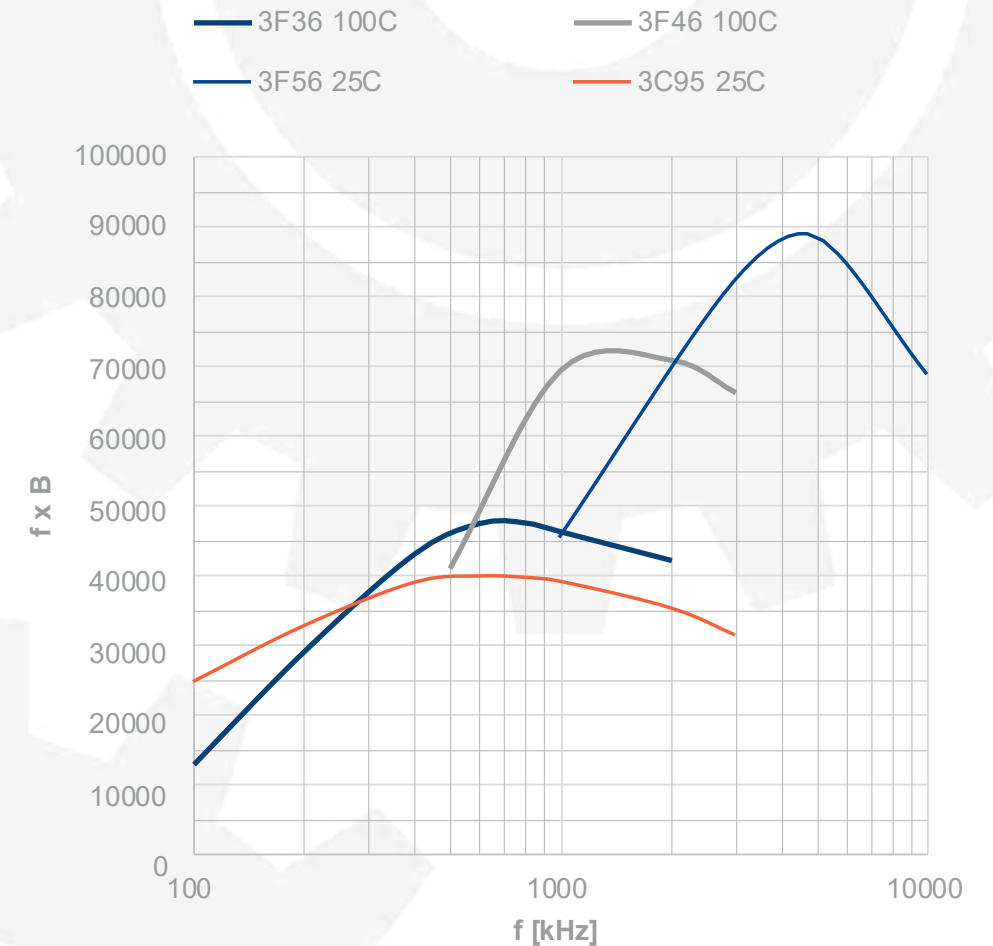
Summary High Frequency

Material	High DC	Core size*	Temp**	Freq range
3C97A	Best	All	<160	< 300 kHz
3C97	Best	All	< 140	< 400 kHz
3C97T	Good	All	< 100	< 400 kHz
3F36	Good	All	< 100	< 1 MHz
3F46	Good	Small Mid	< 100	1 to 3 MHz
3F46A	No	Small Mid	< 80	1 to 3 MHz
3F56	No	Small Mid	< 80	3 to 5 MHz
4F1	Low	All	< 120	≤ 15 MHz

*Small Mid means roughly $A_e < 130 \text{ mm}^2$

**Recommended operating temp, can be exceeded if needed

f_xB @500mW/cm³





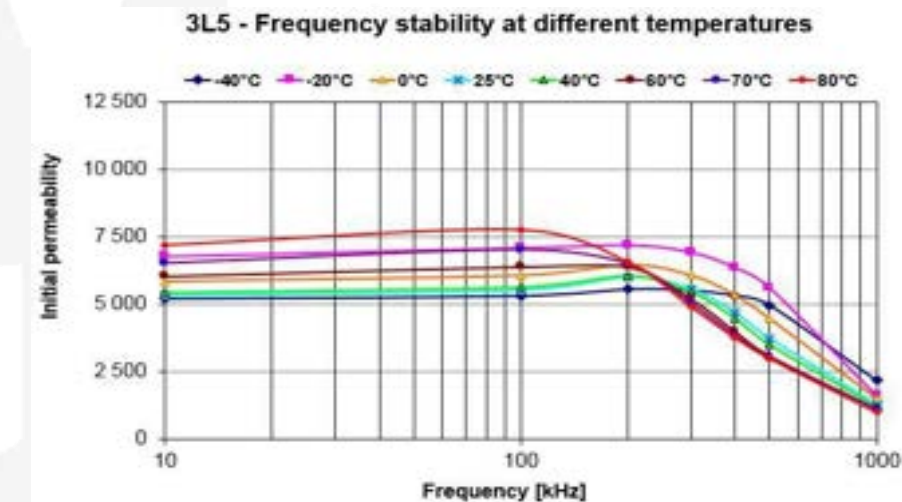
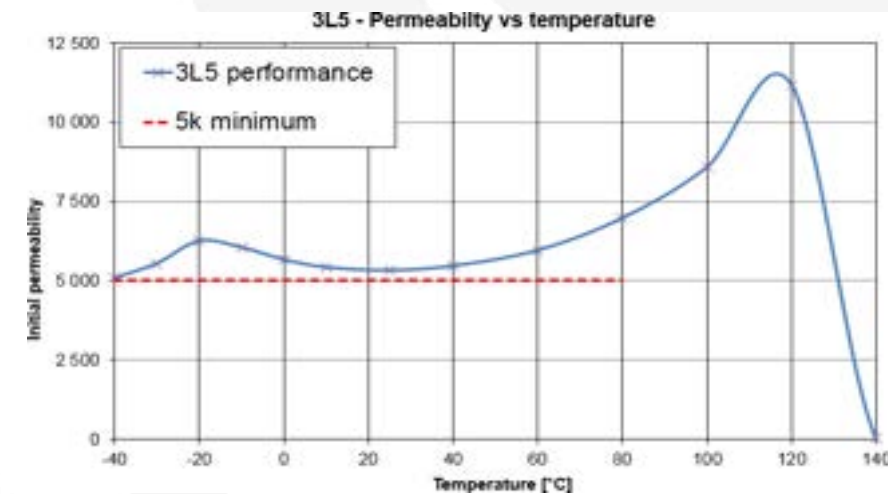
3L5 – High permeability below 0

Permeability > 5k Optimized for -40 to 80 °C Full range of sizes

Operating temp up to 120 °C

Preliminary spec

Symbol		Conditions			Value	Unit
		f (kHz)	B (mT)	T (°C)		
μ_i	Initial permeability	10	0.25	-40	≈ 5000	-
				0	≈ 5500	
				25	≈ 5000	
				70	≈ 5500	
		f (kHz)	H (A/m)	T (°C)		
B	Flux density	10	1200	25	≈ 400	mT
				100	≈ 200	
		f (kHz)	B (mT)	T (°C)		
$\tan\delta/\mu_i$	Relative loss factor	100 200	0.25	25	≤ 15	10^{-6}
					≤ 35	
ρ	Spec. Resistivity DC	-	-	25	≈ 0.5	Ωm
T _C	Curie temperature	10	0.1	-	> 120	°C
SD	Sinter density				≈ 4900	kg/m ³





3E8T – Best balance high μ 8000 / high $T_c > 150^\circ\text{C}$

High permeability (8k)

Low frequency range (0.1-10 MHz)

Small and mid size (<42 mm) range of toroid sizes and cable shields

High $T_c > 150^\circ\text{C}$ provides also high B_{sat}

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	8000 $\pm$ 30%	
B	25°C; 10kHz; 1200A/m	$\approx$ 470	mT
	100°C; 10kHz; 1200A/m	$\approx$ 300	
$\tan\delta/\mu_i$	25°C; 30kHz; 0.25mT	$\leq 5 \cdot 10^{-6}$	
	25°C; 100kHz; 0.25mT	$\leq 30 \cdot 10^{-6}$	
ρ_{DC}	25°C	$\approx$ 0.5	Ωm
T_c		$\geq$ 150	$^\circ\text{C}$
density		$\approx$ 5000	kg/m^3

Typical performance of unstressed ring T25/15/12

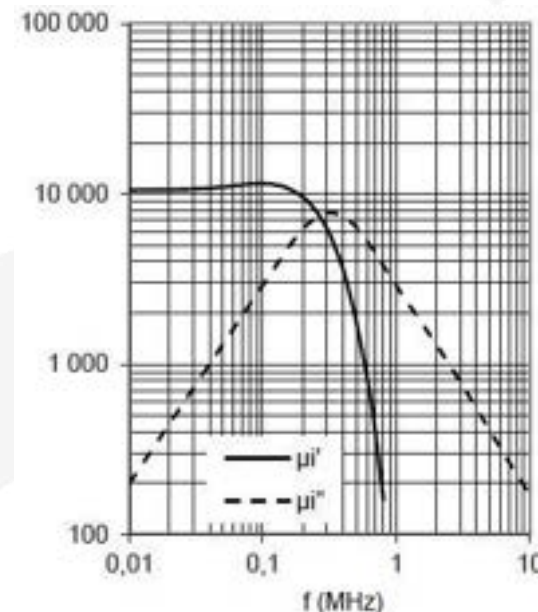


Fig.1 Complex permeability as function of frequency.

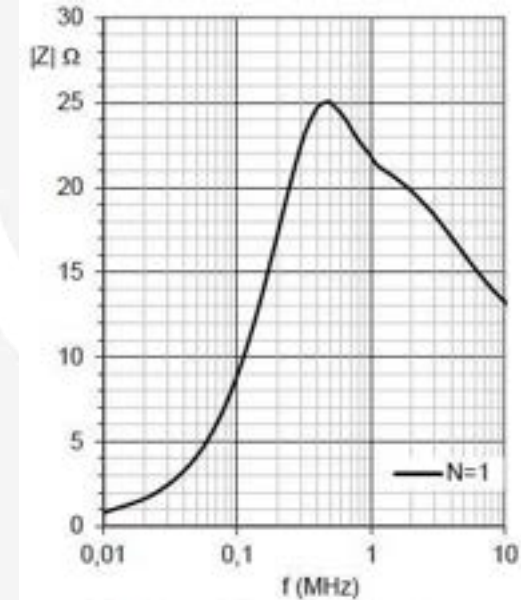


Fig.5 Impedance as function of frequency.

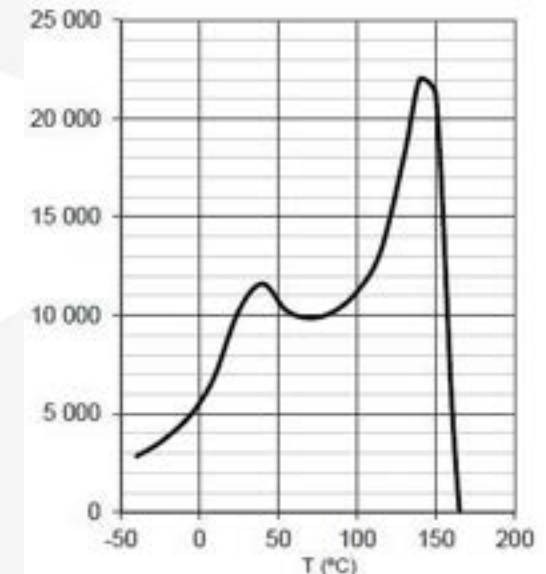


Fig.2 Initial permeability as function of temperature.

3N10 – High Impedance at Low Frequency

High permeability (8k)

Low frequency range (0.1-10 MHz)

Full range of toroid sizes and cable shields

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 8000	
B	25°C; 10kHz; 1200A/m	≈ 460	mT
	100°C; 10kHz; 1200A/m	≈ 270	
$Z C_1 / N^2$	25°C; 0.3MHz; 0.25mT	≈ 14	Ω/mm
	25°C; 1MHz; 0.25mT	≈ 26	
ρ_{DC}	25°C	≈ 0.5	Ωm
Tc		≥ 130	°C
density		≈ 5000	kg / m^3

Measured on T14/9/5

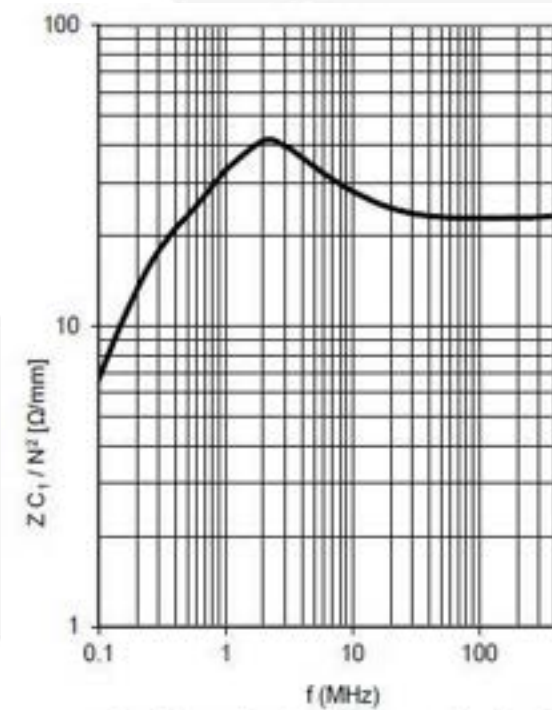


Fig.4 Normalized impedance as a function of frequency

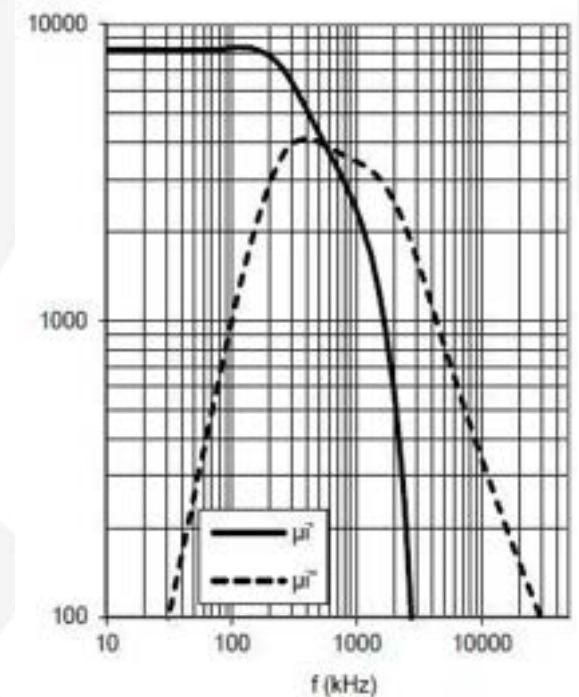


Fig.1 Complex permeability as a function of frequency



3N5 – Highest Impedance mediumF with $T_c > 150^\circ\text{C}$

Medium permeability (5k)

Broad frequency range T_c

$> 150^\circ\text{C}$

Full range of sizes including toroids,
cable shields and shapes (E, U...)

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 6000	
B	25°C; 10kHz; 1200A/m	≈ 460	mT
	100°C; 10kHz; 1200A/m	≈ 300	
$Z C_1 / N^2$	25°C; 1MHz; 0.25mT	≈ 22	Ω/mm
	25°C; 3MHz; 0.25mT	≈ 41	
ρ_{DC}	25°C	≈ 0.5	Ωm
T_c		≥ 150	$^\circ\text{C}$
density		≈ 4850	kg / m^3

Measurd on T14/9/5

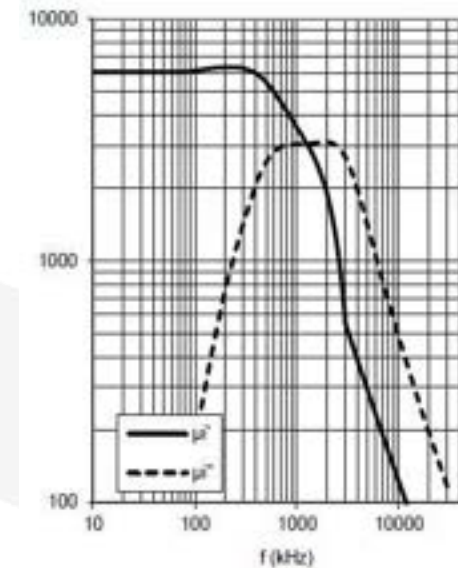
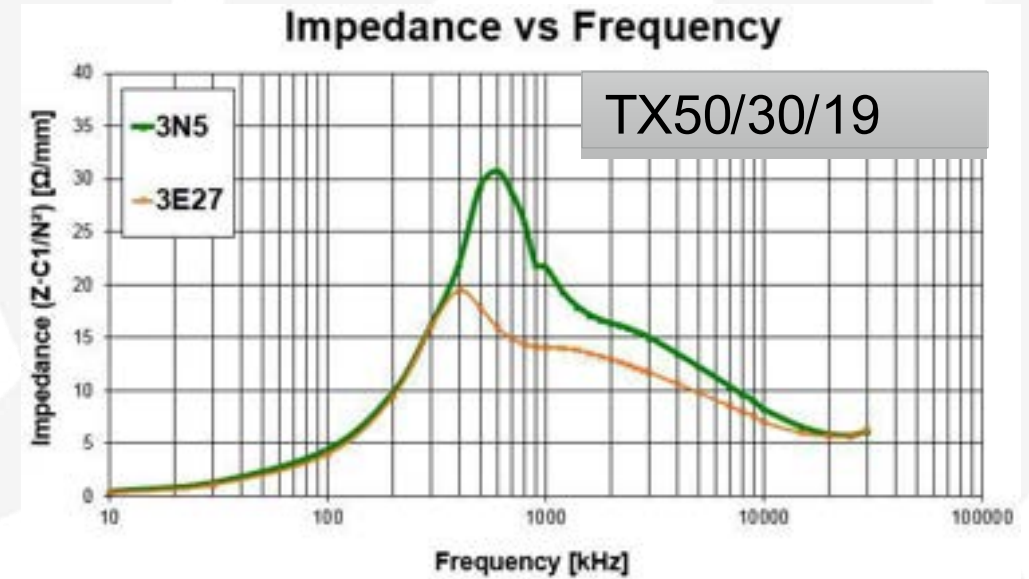


Fig.1 Complex permeability as a function of frequency

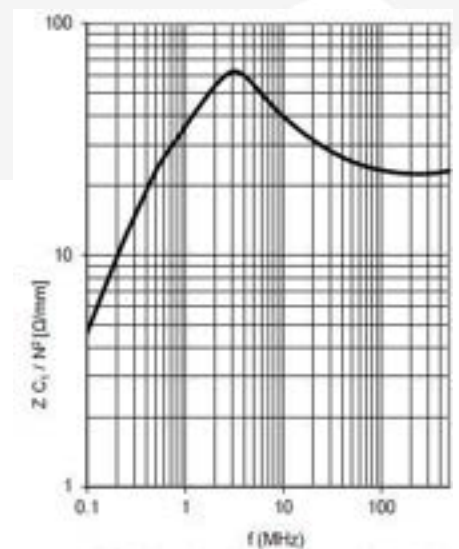


Fig.4 Normalized impedance as a function of frequency



3N4 – Highest Impedance medium F with $T_c > 200^\circ\text{C}$

Medium permeability

Broad frequency range (1-10 MHz)

$T_c > 200^\circ\text{C}$

Full range of sizes including toroids, cable shields and shapes (E, U...)

High B_{sat} , suitable for strong CM noise

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 2500	
B	25°C; 10kHz; 1200A/m	≈ 530	mT
	100°C; 10kHz; 1200A/m	≈ 410	
$Z C_1 / N^2$	25°C; 3MHz; 0.25mT	≈ 42	Ω/mm
	25°C; 5MHz; 0.25mT	≈ 47	
ρ_{DC}	25°C	≈ 10	Ωm
T_c		≥ 200	$^\circ\text{C}$
density		≈ 4800	kg / m^3

Measurd on T14/9/5

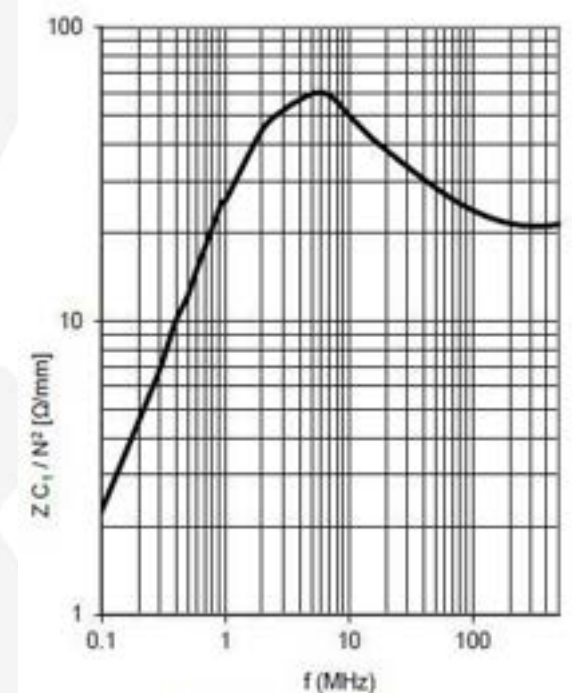
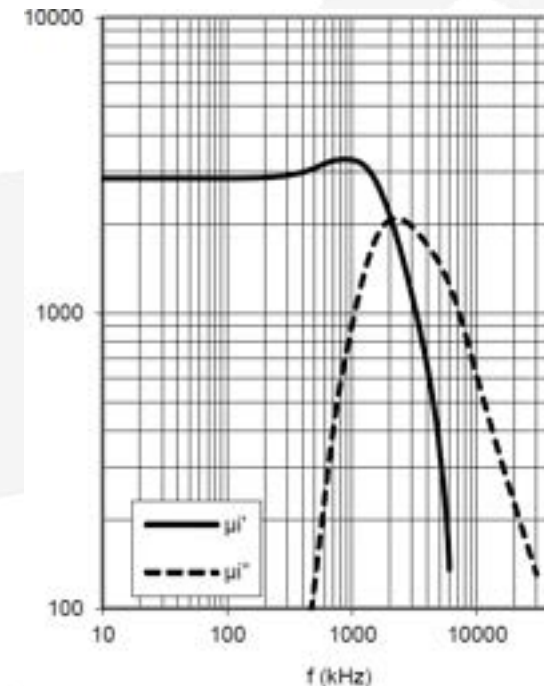


Fig.4 Normalized impedance as a function of frequency



3N3 – Highest Impedance medium F with $T_c > 200^{\circ}\text{C}$

Low permeability

Broad frequency range (1-10 MHz)

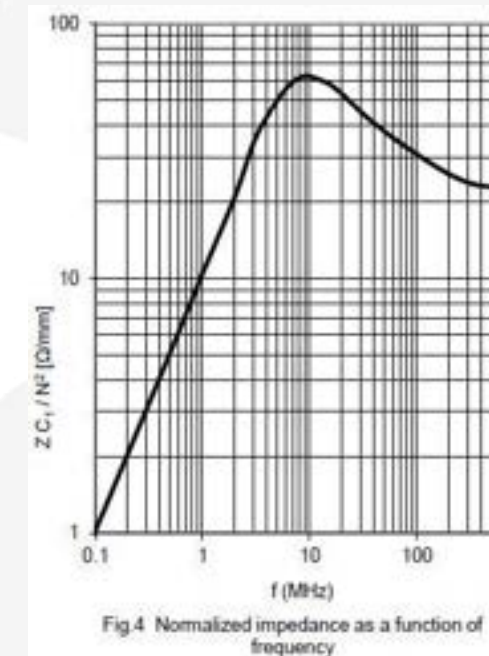
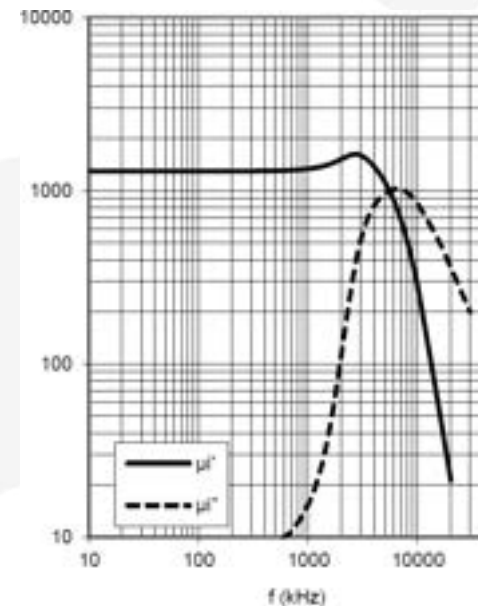
$T_c > 200^{\circ}\text{C}$

Full range of sizes including toroids, cable shields and shapes (E, U...)

High B_{sat} , suitable for strong CM noise

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 1250	
B	25°C; 10kHz; 1200A/m	≈ 520	mT
	100°C; 10kHz; 1200A/m	≈ 420	
$Z C_1 / N^2$	25°C; 5MHz; 0.25mT	≈ 40	Ω/mm
	25°C; 10MHz; 0.25mT	≈ 50	
ρ_{DC}	25°C	≈ 15	Ωm
T_c		≥ 200	$^{\circ}\text{C}$
density		≈ 4750	kg / m^3

Measurd on T14/9/5





3N2 – Full bandwidth filtering

Full bandwidth filtering thanks to relatively high permeability (3k) for low frequency suppression and high frequency impedance beyond 100 MHz

Low remanence, stable permeability and impedance after magnetization

$T_c > 150^\circ\text{C}$

New!

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 3000	
$\mu_{\text{resonance}}$	25°C; 10kHz; 0.25mT	≈ 3000	
B	25°C; 10kHz; 1200A/m	≈ 410	mT
	100°C; 10kHz; 1200A/m	≈ 260	
$Z C_1 / N^2$	25°C; 3MHz; 0.25mT	≈ 35	Ω/mm
	25°C; 30MHz; 0.25mT	≈ 61	
	25°C; 100MHz; 0.25mT	≈ 71	
ρ_{DC}	25°C	$\approx 10^3$	Ωm
T_c		≥ 150	$^\circ\text{C}$
density		≈ 4800	kg / m^3

Measured on T14/9/5

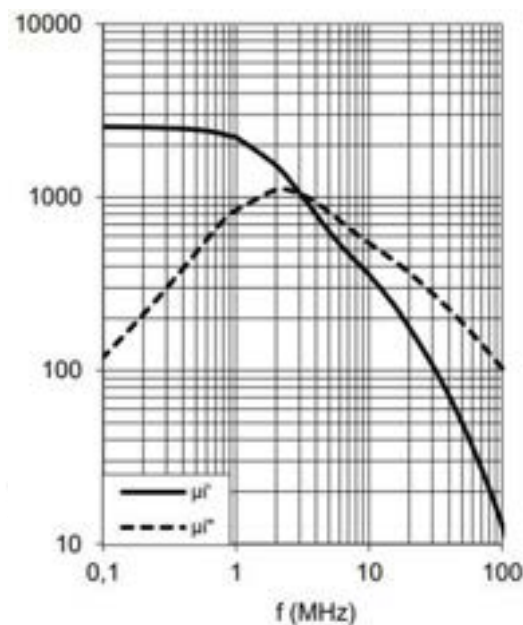


Fig.1 Complex permeability as a function of frequency

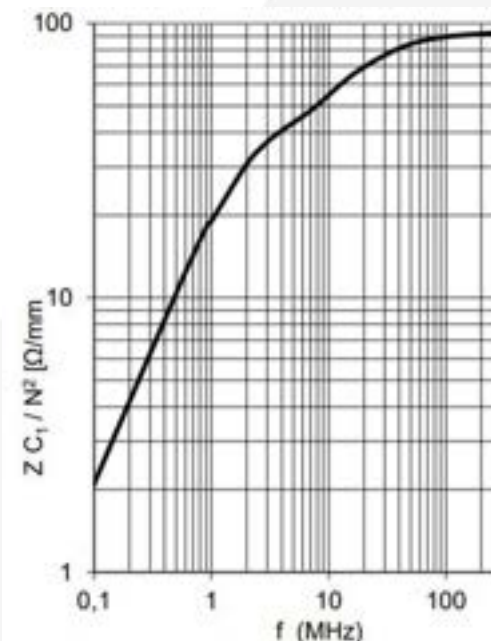


Fig.4 Normalized impedance as a function of frequency

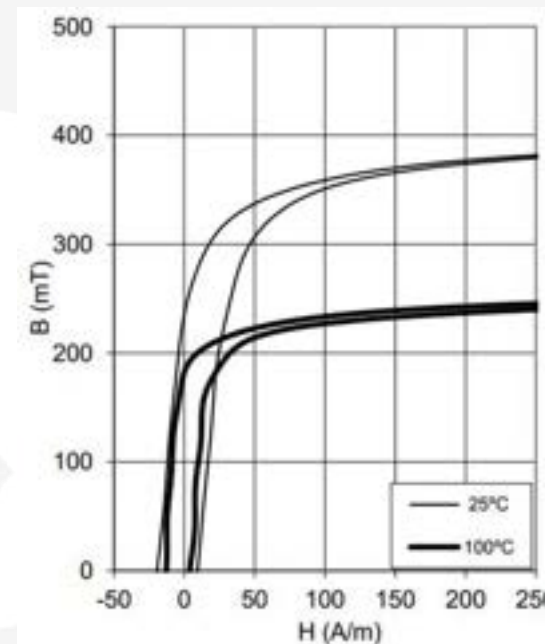


Fig.3 Typical BH loop



3N1T

High resistivity MnZn, alternative to NiZn

High Bsat and high Tc

Ideal for common mode chokes for 30 to 100 MHz

3N1T SPECIFICATION

An EMI-suppression material for conducted and radiated emissions up to 300 MHz with a maximum impedance in the frequency range 30 to 100 MHz.

SYMBOL	CONDITIONS	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 1100	
B	25°C; 10kHz; 1200A/m	≈ 450	mT
	100°C; 10kHz; 1200A/m	≈ 350	
Z_{C_1} / N^2	25°C; 10MHz; 0.25mT	≈ 25	Ω/mm
	25°C; 100MHz; 0.25mT	≈ 56	
Pv	100°C; 100kHz; 100mT	≈ 350	kW/m ³
ρ_{DC}	25°C	$\approx 10^3$	Ωm
Tc		≥ 200	°C
density		≈ 4800	kg / m ³

Measured on T14/9/5

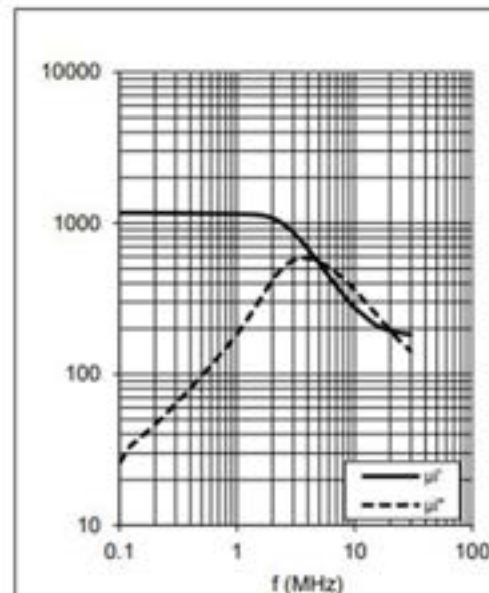


Fig.1 Complex permeability as a function of frequency

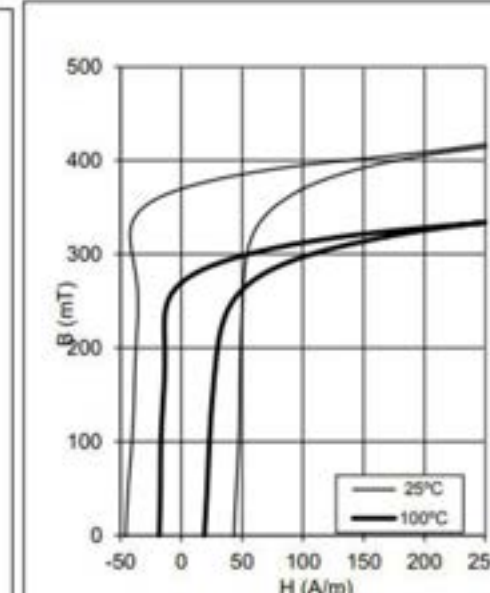


Fig.3 Typical BH loop

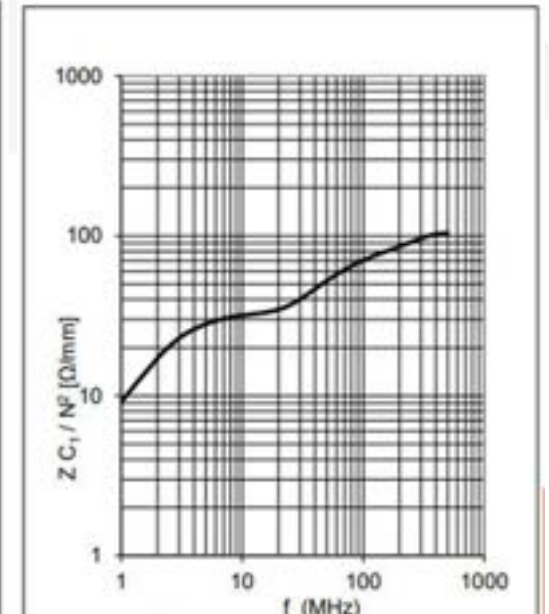


Fig.4 Normalized impedance as a function of frequency at 25°C



3N1 – 3N2 – 3N1T – 3N2T

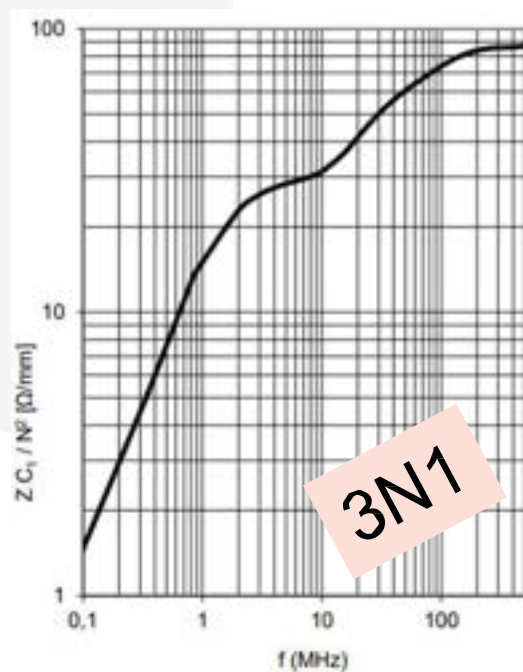
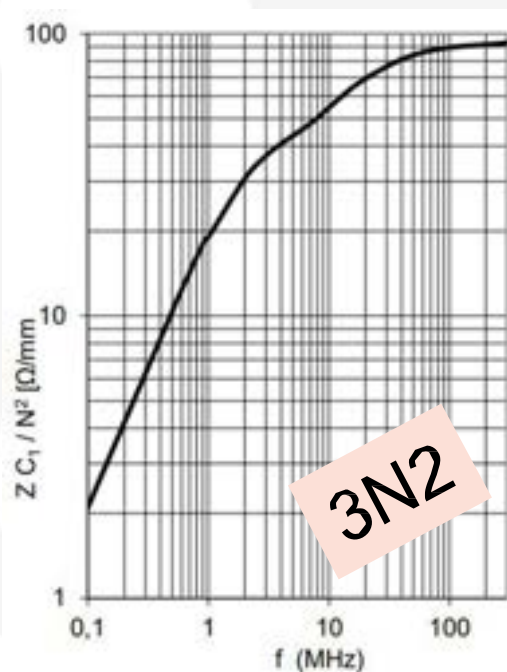
$T_c > 150$

3N2:

- High impedance 0.1 to 30 MHz
- High permeability $\mu=3000$

3N1:

- Cost effective



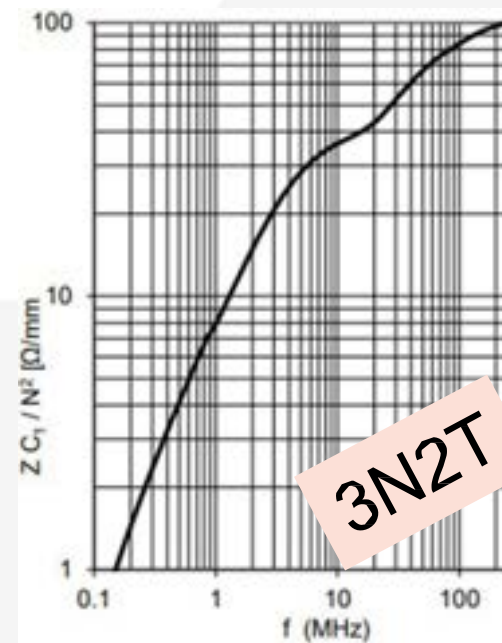
$T_c > 200$

3N2T:

- High impedance 0.1 to 30 MHz
- Better temperature stability

3N1T: only for large volume

- Cost effective





3N series – Impedance table

3N10	3N5	3N4	3N3	3N1
------	-----	-----	-----	-----

SYMBOL	Conditions	VALUE	VALUE	VALUE	VALUE	VALUE	UNIT
μ_i	25°C; 10kHz; 0.25mT	≈ 8000	≈ 6000	≈ 2500	≈ 1250	≈ 1800	-
B	25°C; 10kHz; 1200A/m 100°C; 10kHz; 1200A/m	≈ 460 ≈ 270	≈ 460 ≈ 300	≈ 530 ≈ 410	≈ 520 ≈ 420	≈ 420 ≈ 280	mT
Z_{c1/n^2}	25°C; 0.1MHz; 0.25mT	≈ 5	≈ 3	≈ 2	≈ 1	≈ 1	Ω/mm
	25°C; 0.3MHz; 0.25mT	≈ 14	≈ 8	≈ 6	≈ 2	≈ 4	
	25°C; 0.5MHz; 0.25mT	≈ 19	≈ 14	≈ 10	≈ 4	≈ 6	
	25°C; 1MHz; 0.25mT	≈ 26	≈ 22	≈ 20	≈ 7	≈ 12	
	25°C; 3MHz; 0.25mT	≈ 32	≈ 41	≈ 42	≈ 27	≈ 21	
	25°C; 5MHz; 0.25mT	≈ 27	≈ 45	≈ 47	≈ 40	≈ 23	
	25°C; 10MHz; 0.25mT	≈ 23	≈ 33	≈ 40	≈ 50	≈ 25	
	25°C; 30MHz; 0.25mT	≈ 19	≈ 23	≈ 27	≈ 36	≈ 40	
	25°C; 100MHz; 0.25mT	≈ 18	≈ 19	≈ 19	≈ 25	≈ 59	
	25°C; 300MHz; 0.25mT	≈ 18	≈ 18	≈ 17	≈ 19	≈ 69	
ρ	DC; 25°C	≈ 0.5	≈ 0.5	≈ 10	≈ 15	≈ 10 ³	Ωm
T _c		≥ 130	≥ 150	≥ 200	≥ 200	≥ 150	°C
Density		≈ 5000	≈ 4850	≈ 4800	≈ 4750	≈ 4800	kg/m ³